



EMI-FILTER VON DER KOMPONENTE ZUM DESIGN

Mario Möller
Field Application Engineer

WÜRTH ELEKTRONIK MORE THAN YOU EXPECT

Reichs-Gesetzblatt.

№ 21.

Inhalt: Gesetz über das Telegraphenwesen des Deutschen Reichs. S. 467.

(Nr. 2015.) Gesetz über das Telegraphenwesen des Deutschen Reichs. Vom 6. April 1892.

Wir Wilhelm, von Gottes Gnaden Deutscher Kaiser, König von Preußen u.

verordnen im Namen des Reichs, nach erfolgter Zustimmung des Bundesraths und des Reichstags, was folgt:

§. 12.

Elektrische Anlagen sind, wenn eine Störung des Betriebes der einen Leitung durch die andere eingetreten oder zu befürchten ist, auf Kosten desjenigen Theiles, welcher durch eine spätere Anlage oder durch eine später eintretende Aenderung seiner bestehenden Anlage diese Störung oder die Gefahr derselben veranlaßt, nach Möglichkeit so auszuführen, daß sie sich nicht störend beeinflussen.

WO KOMMEN DIE STÖRER HER?

Origin of EMI

- Clock Signals

- z.B. 25MHz, 2.6GHz



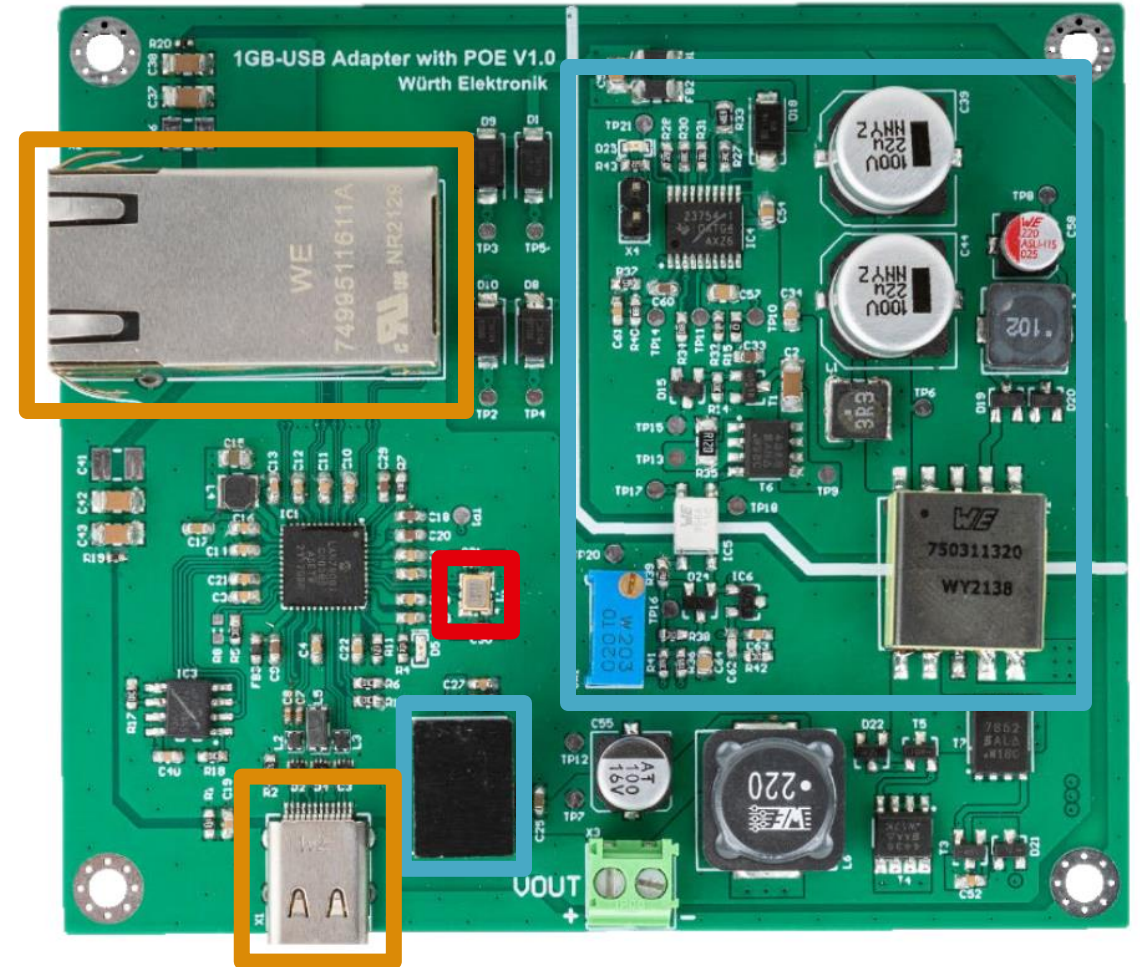
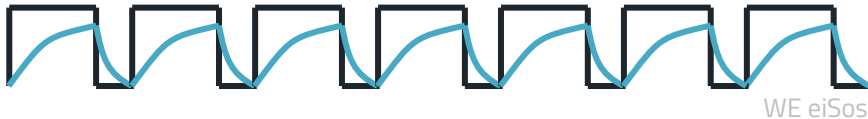
- Datalines

- z.B. USB 2.0 480Mbps, SATA II 300Mbps



- DC/DC Converters

- 150 kHz – 10 MHz



Entstehung von Überspannung

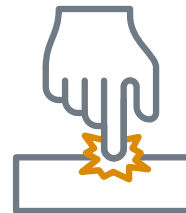
- Natürliche Phänomene
 - z.B.: indirekter Blitzschlag



- Industrielle Entladungen
 - z.B.: Schalten induktiver Lasten



- Elektrostatische Entladung
 - z.B.: zwischen Mensch und Material



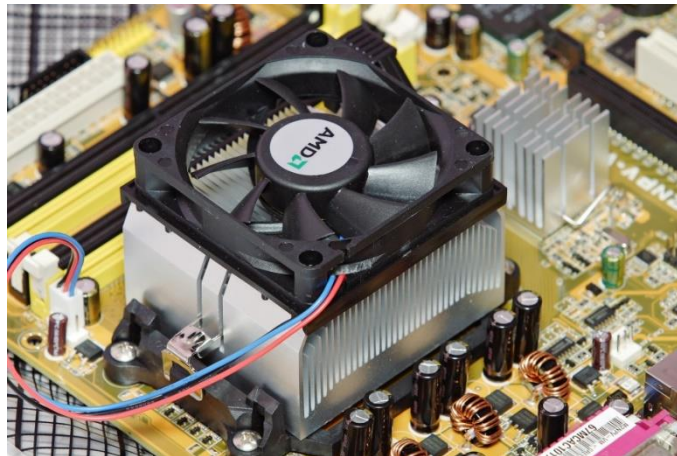
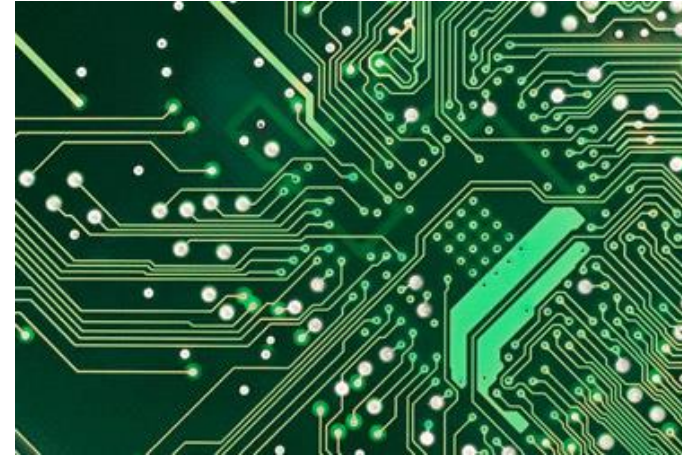
- EN 61000-4-5
 - Surge mit hoher Energie

- EN 61000-4-4
 - EFT

- EN 61000-4-2
 - ESD

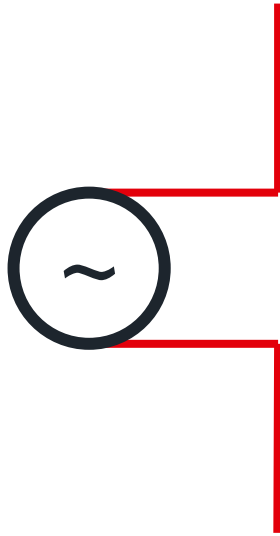
WIE VERBREITEN SICH DIE STÖRER?

Jeder Leiter ist eine Antenne

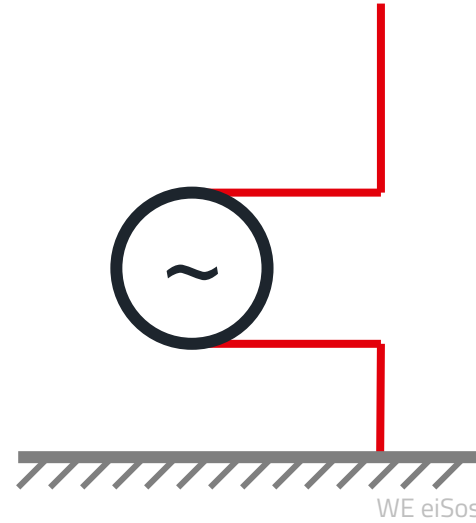


- Kabel
- Leiterzüge
- Bauteile
- ICs
- Kühlkörper
- Gehäuse

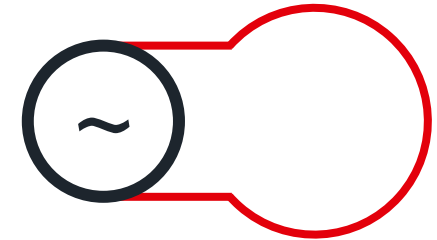
Jeder Leiter ist eine Antenne



Elektrische
Dipolantenne



Elektrische
Monopolantenne

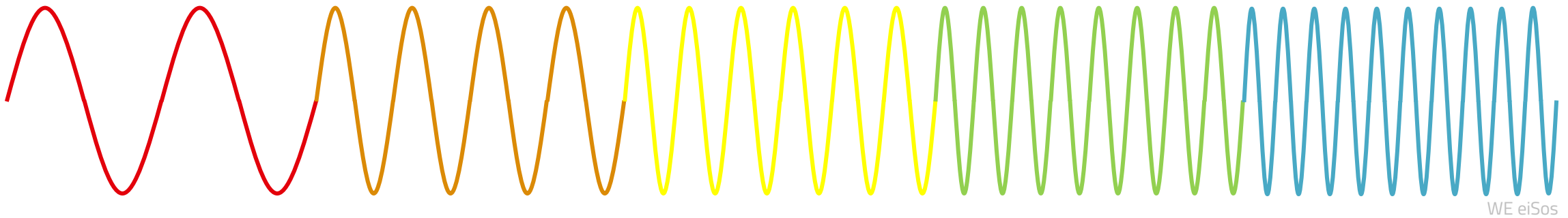


Magnetische
Rahmenantenne

Frequenz und Wellenlänge

$$c = \lambda * F$$

$$c = 300 \times 10^6 \text{ m/s}$$



Niedrige Frequenz
große Wellenlänge

Netzfrequenz 50 Hz
 $\lambda = 6000 \text{ km}$

30 MHz
 $\lambda = 10 \text{ m}$

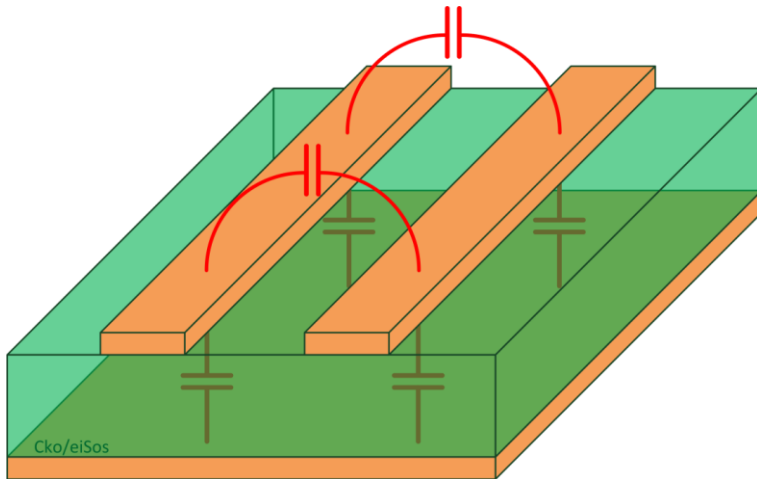
Hohe Frequenz
kleine Wellenlänge

WLAN/ Bluetooth 2,4 GHz
 $\lambda = 12,5 \text{ cm}$

Capacitive Coupling

Origins

- Originates from high dU/dt
- Parallel conductors form a parasitic capacitance
- Coupling capacitance is directly proportional to the length of the parallel trace run



Isolating Components	typ. Coupling Capacitance
Optocoupler	0,5...5 pF
Solid State Relay	0,5...10 pF
Gate Drive Transformer	2...10 pF
Electromechanical Relay	10...100 pF
Digital Isolator	100...200 pF
Digital Isolator (int. SMPS)	300...600 pF
Transformers in SMPS	Up to 1000 pF

Capacitive Coupling

Effects

- Voltage interference at the load:

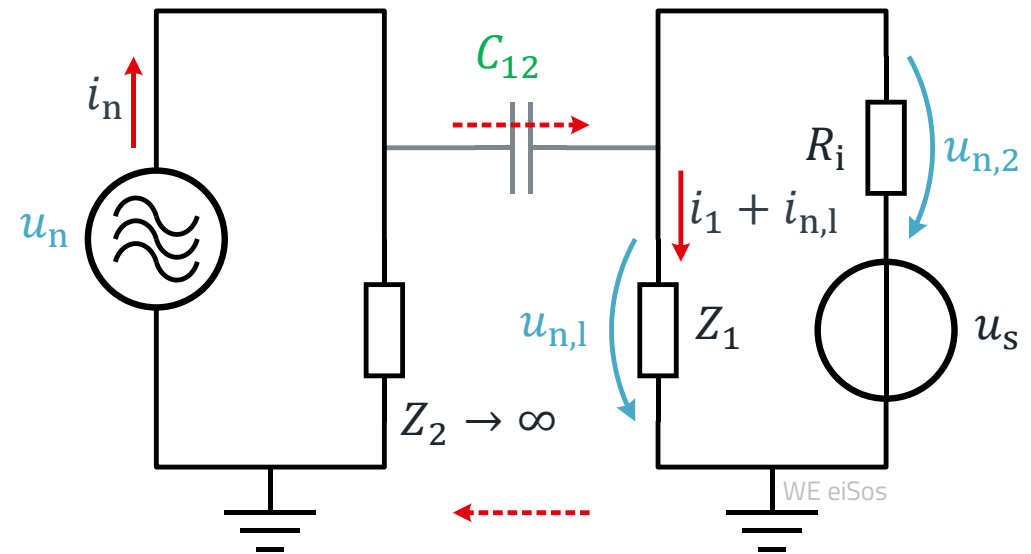
$$u_{n,l} = i_n \cdot \frac{R_i \cdot Z_1}{R_i + Z_1} = C_{12} \cdot \frac{du_n}{dt} \cdot \frac{R_i \cdot Z_1}{R_i + Z_1}$$

- Laplace made easy: replace $\frac{d}{dt}$ by $j\omega$

$$U_{n,l} = U_n \cdot j\omega C_{12} \cdot \frac{R_i \cdot Z_1}{R_i + Z_1}$$

$$C_{12} = \epsilon \cdot \frac{A}{d}$$

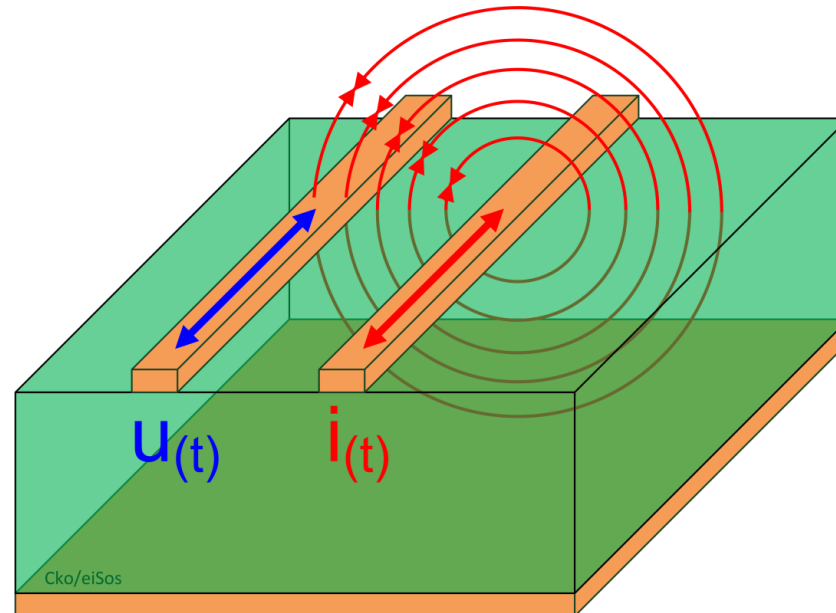
- Doubling the frequency doubles the crosstalk (+6 dB)
- Doubling the sink impedance ($R_i || Z_1$) doubles the crosstalk



Inductive Coupling

Origins

- Originates from high di/dt
- Parallel traces form a parasitic transformer
- Mutual Inductance increases with shorter distance



Inductive Coupling

Effects

- Voltage interference at the load ($Z_1 = \text{Near End}$):

$$u_{n,l} = M_{12} \cdot \frac{di_n}{dt} \cdot \frac{Z_1}{R_i + Z_1}$$

- Laplace made easy: replace $\frac{d}{dt}$ by $j \omega$

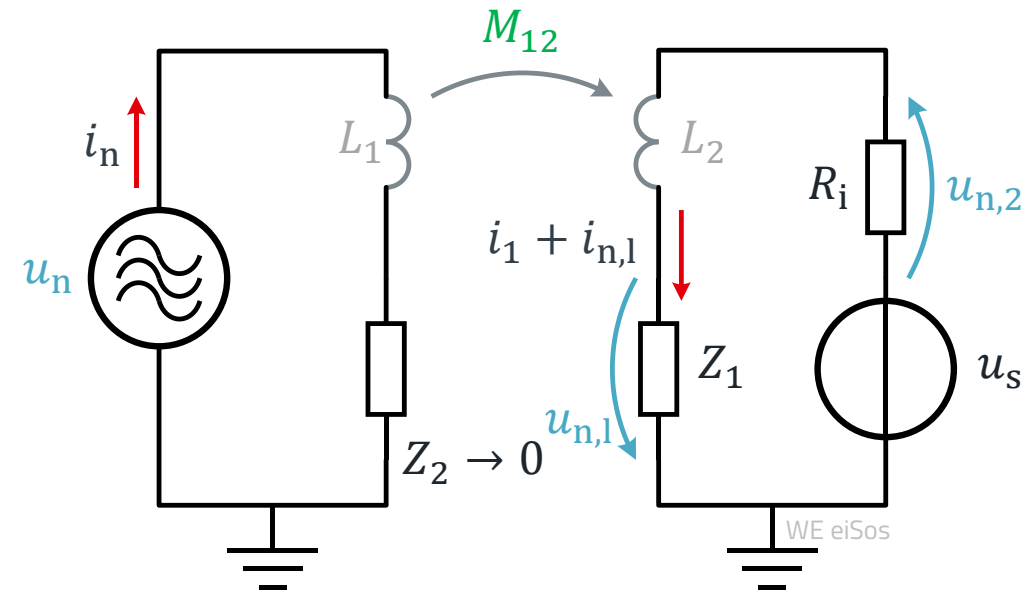
$$U_{n,l} = I_n \cdot j \omega M_{12} \cdot \frac{Z_1}{R_i + Z_1}$$



$$M_{12} = \mu \cdot N_1 N_2 \cdot \frac{A}{l}$$

- Doubling the frequency doubles the crosstalk (+6 dB)
- Crosstalk increases with inductive loop dimensions
- Lenz's Law: Phase reversal of the induced current can be observed at the far end
- Voltage interference at the source ($R_i = \text{Far End}$):

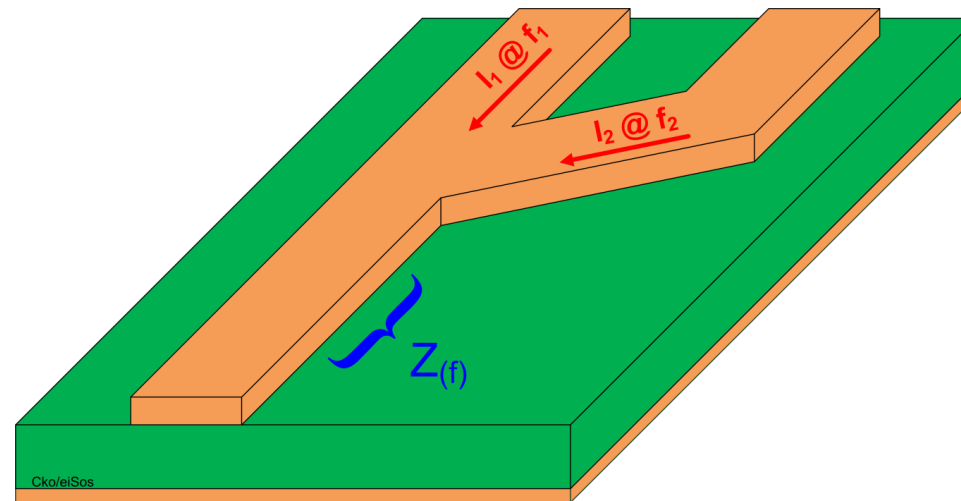
$$U_{n,2} = -I_n \cdot j \omega M_{12} \cdot \frac{R_i}{R_i + Z_1}$$



Impedance Coupling

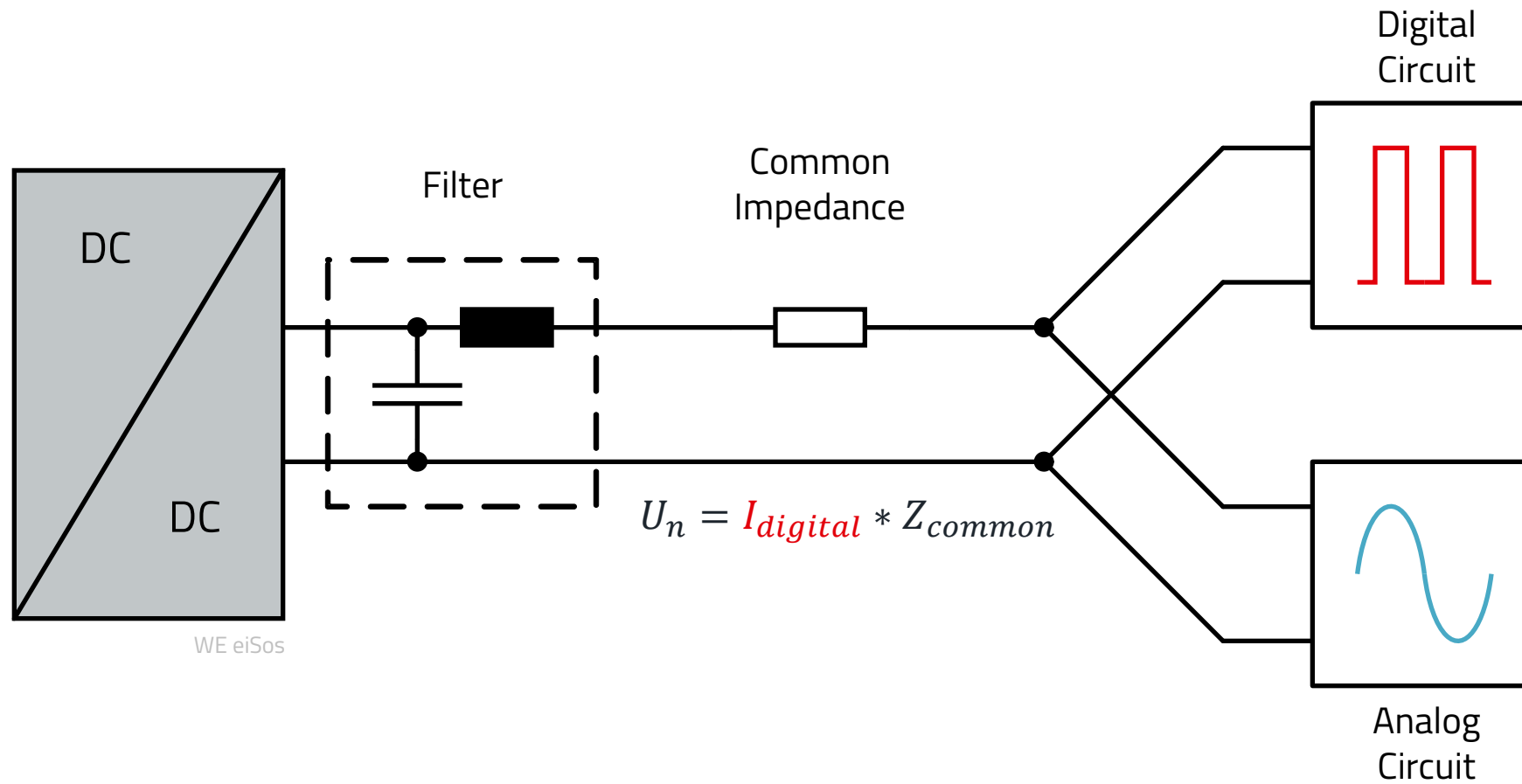
Origins

- Interference affects circuits with a mutual traces
- Circuits share an impedance and therefore the voltage across that impedance
- Main cause for high mutual impedances is self-inductance across copper traces

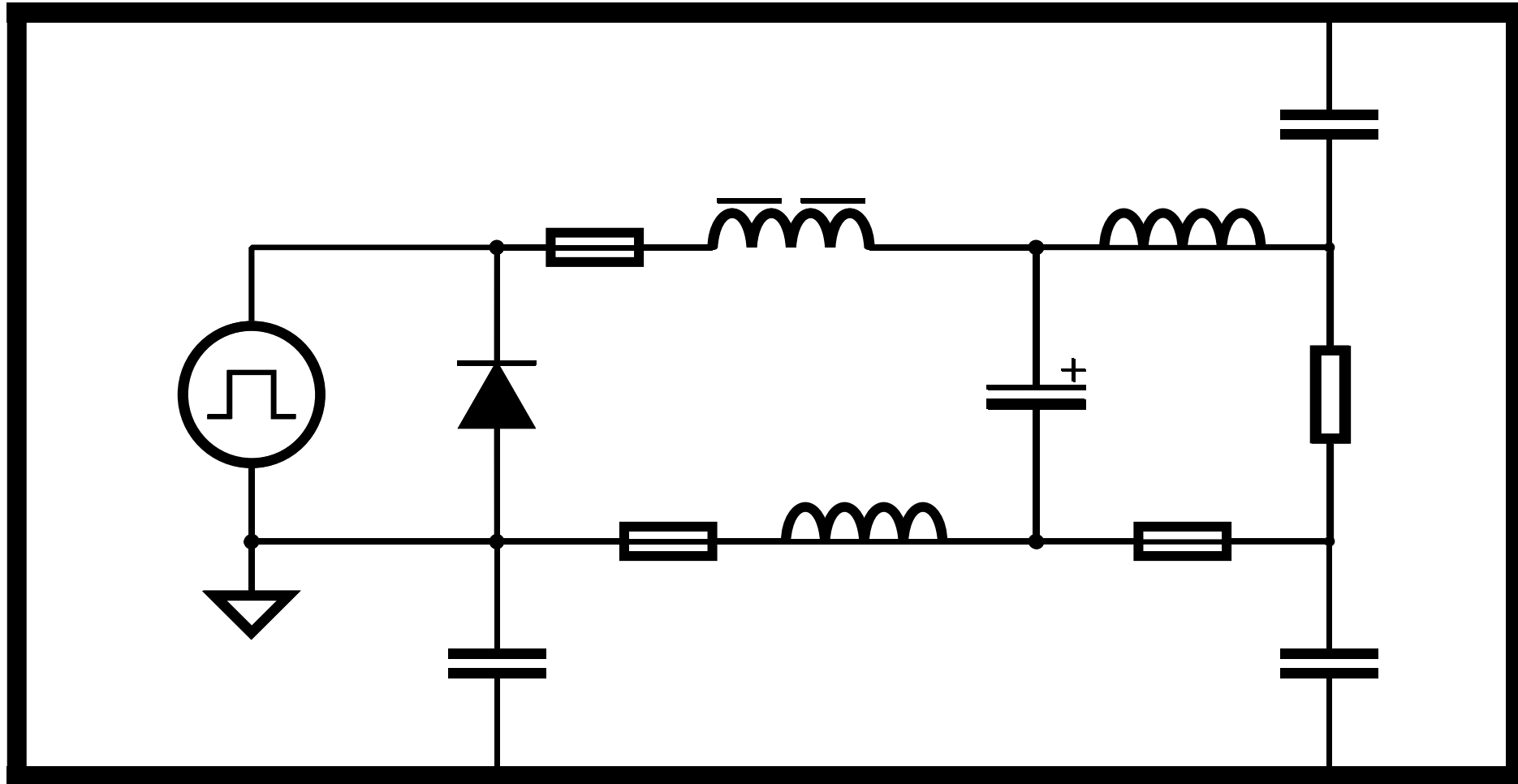


Impedance Coupling

A closer look



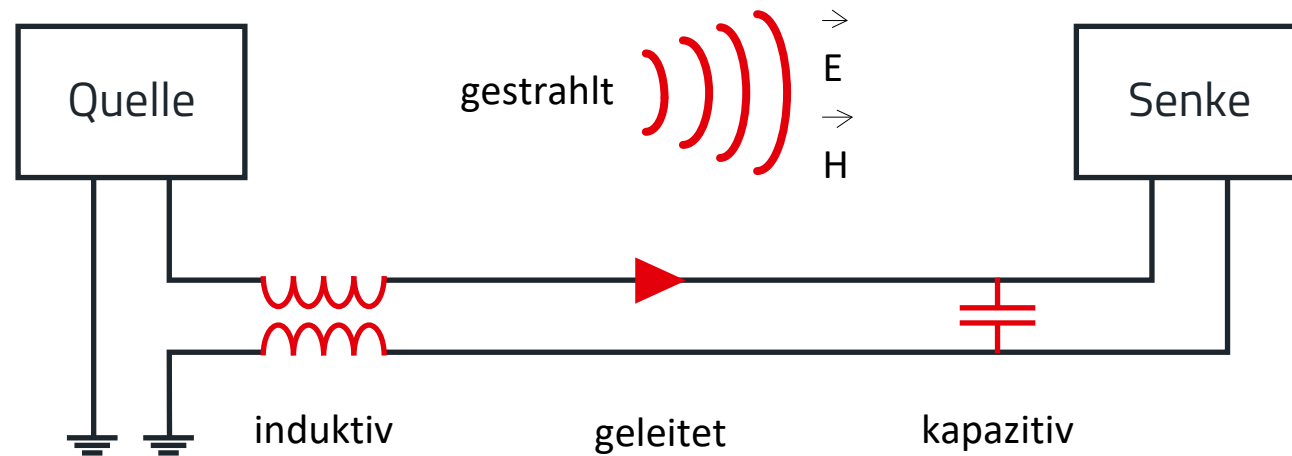
Plan und Resultat



WAS KANN ICH GEGEN STÖRER TUN?

EMV - Maßnahmen

- Ausreichende EMV lässt sich meist durch geeignete Maßnahmen an Sender, Pfad oder Empfänger erreichen.
 - **Primärmaßnahme** Emissionen des Senders minimieren
 - **Sekundärmaßnahme** Unterbrechung der Kopplungsmechanismen
 - **Tertiärmaßnahme** Störfestigkeit des Empfängers erhöhen



Capacitive Coupling

Measures to decrease coupling

- **Primary Measure**

- Decrease dU/dt by selecting a slower signal edges
- A Low pass filter to take off the edges

- **Secondary Measure**

- Shorten/avoid parallel trace runs
- Small areas for switched polygons (e.g. DC/DC switch node)
- Increase distance between affected paths
- Electrical shielding (Cable, PCB, Housing)



Inductive Coupling

Measures to decrease coupling

- **Primary Measure**

- Decrease di/dt by selecting a lower switching frequency and slower signal edges
- A filter Inductor/Ferrite to take off the edges

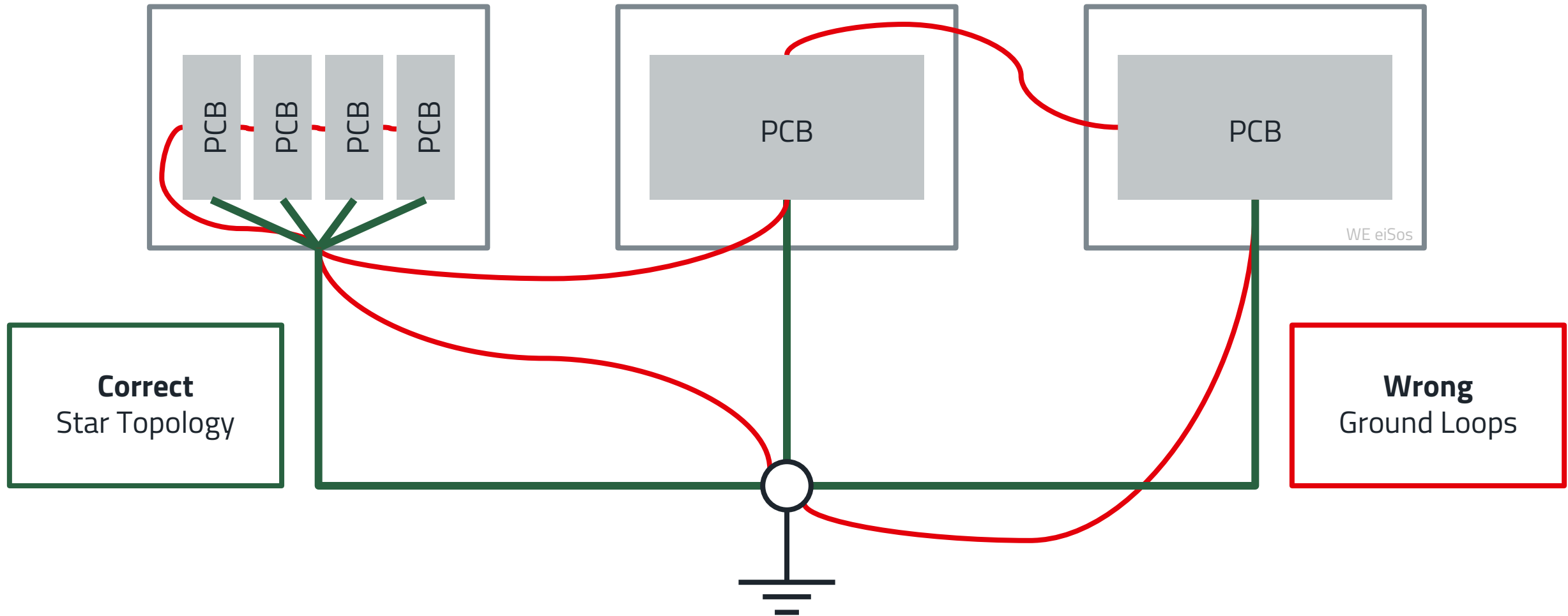
- **Secondary Measure**

- Decrease magnetic loop area
- Increase distance between affected circuits
- Orthogonal component placement
- Magnetic shielding with ferrite materials (soft permeability, high μ_r)



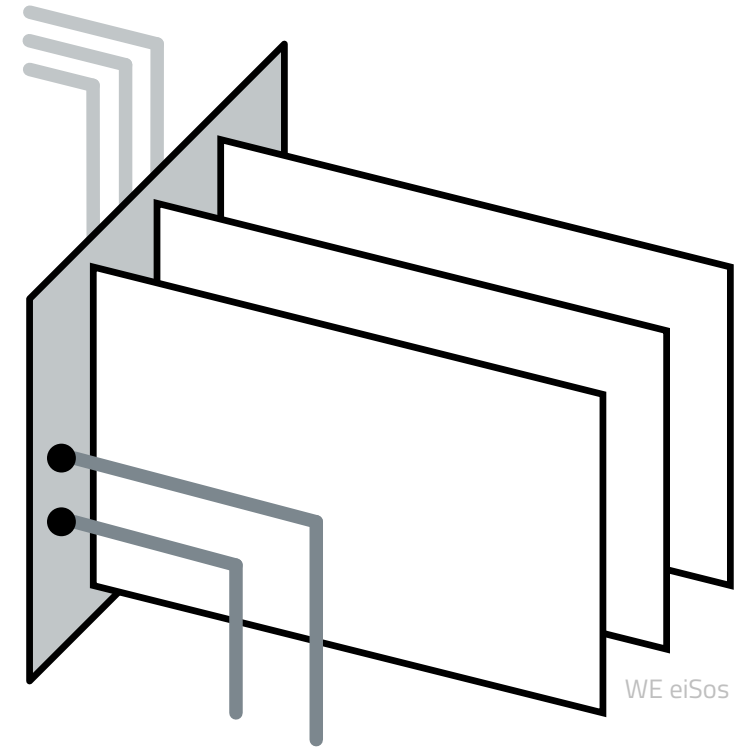
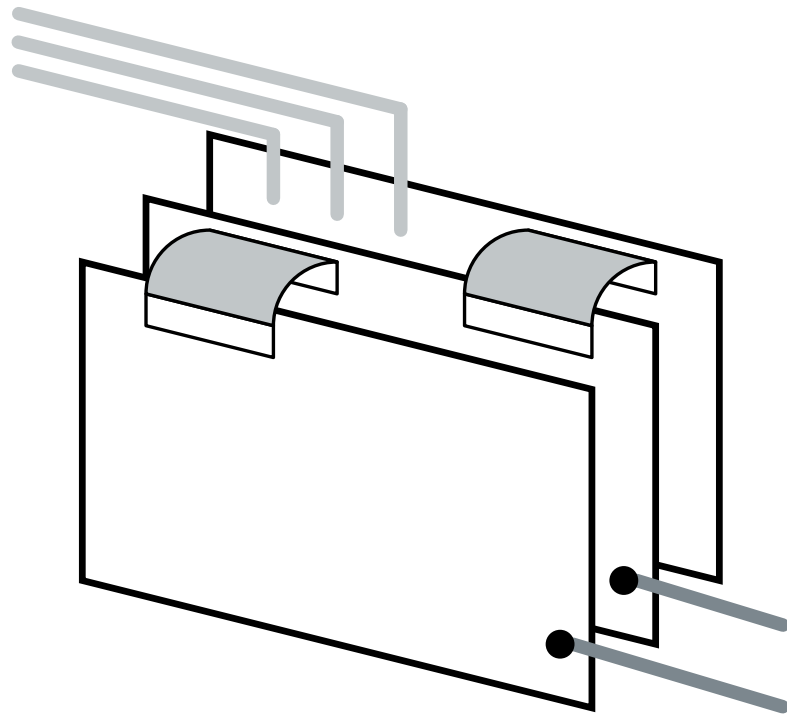
Ground Concept

Distribution across multiple PCBs



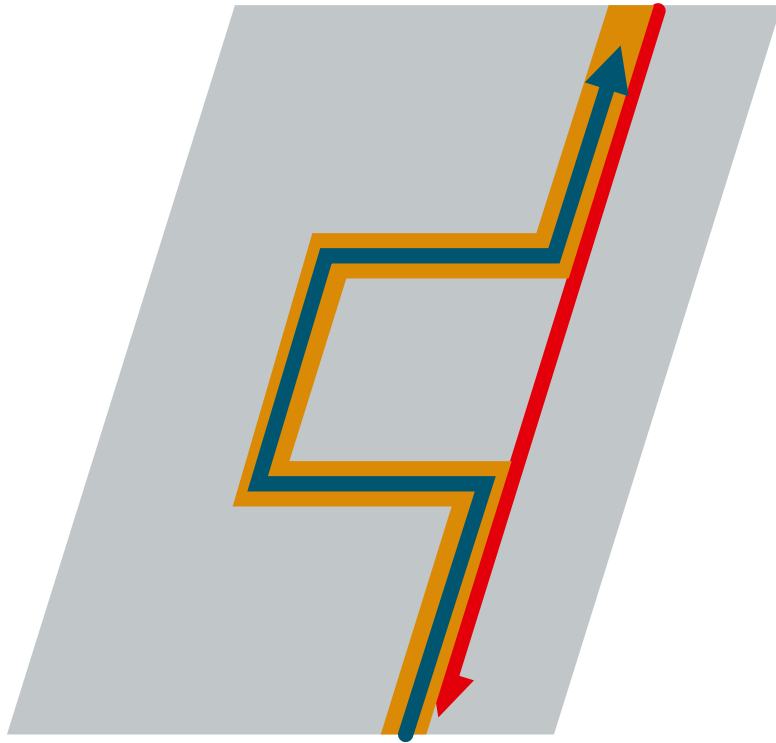
Ground Concept

Distribution across multiple PCBs

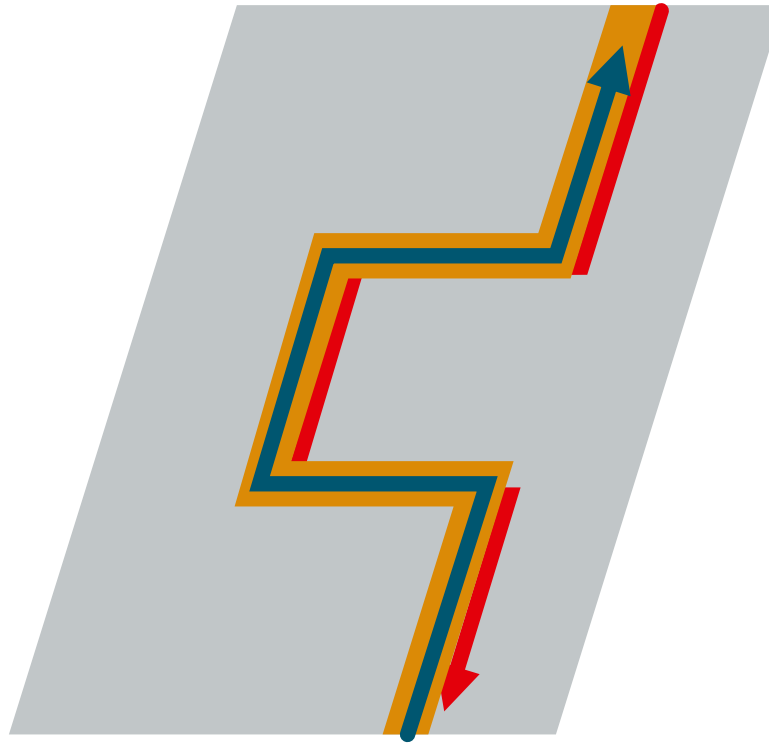


Changes in the Construction can make or break EMC

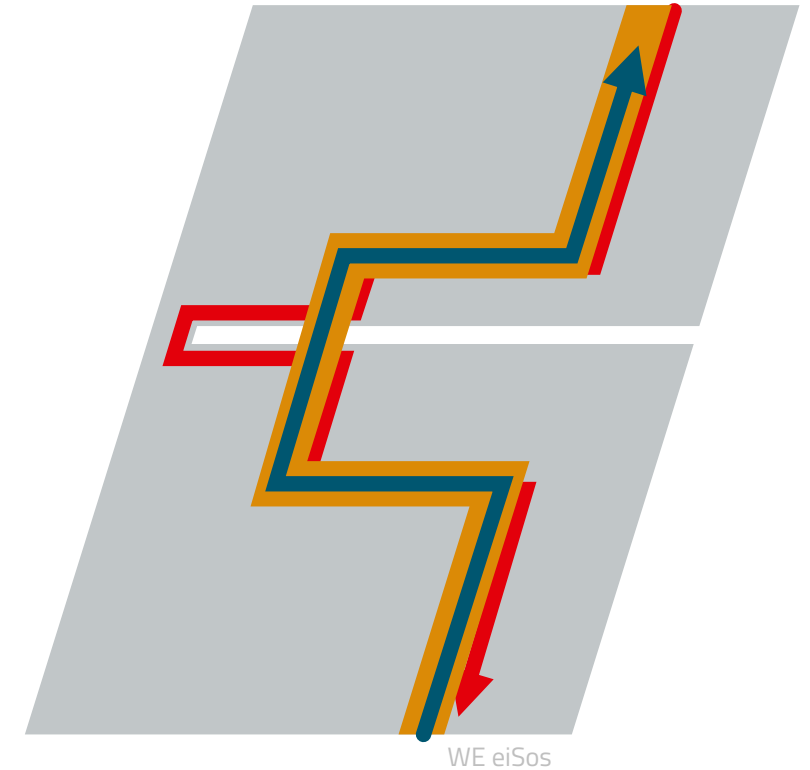
Path of least Impedance



DC Return Path



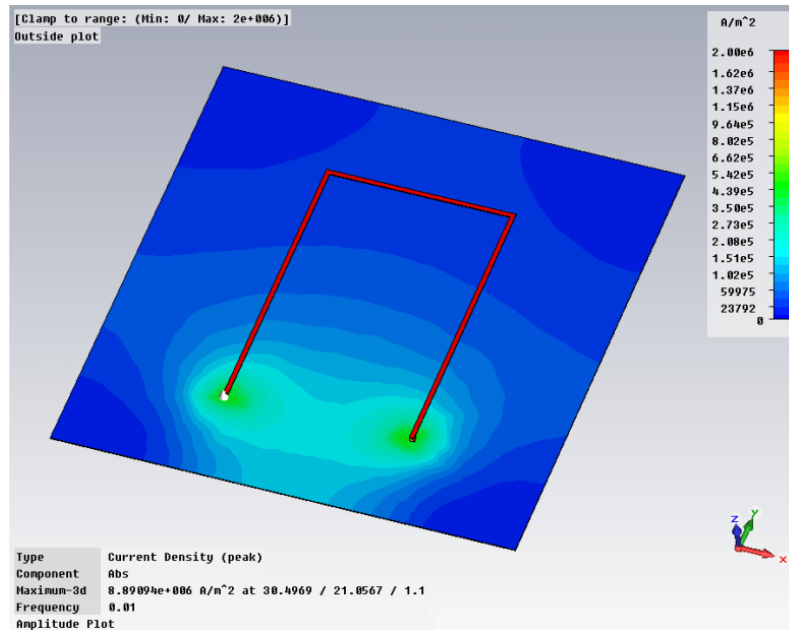
AC Return Path



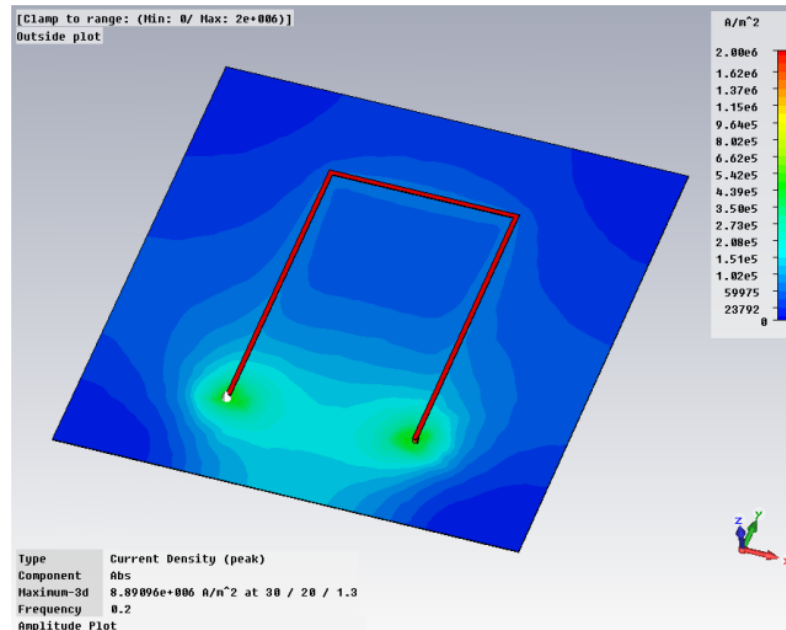
Slotted AC Return Path

Path of least Impedance

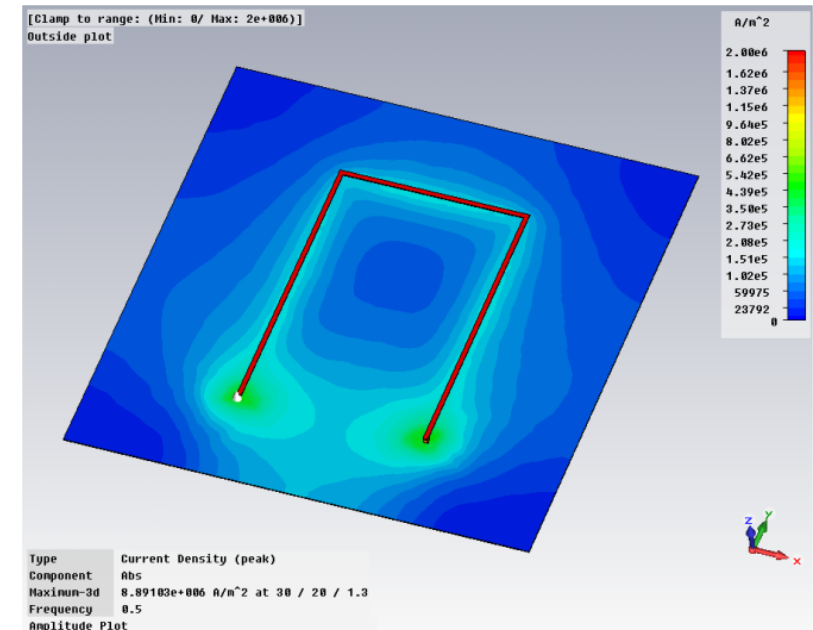
Simulation: Return Path depending on Frequency



10 Hz



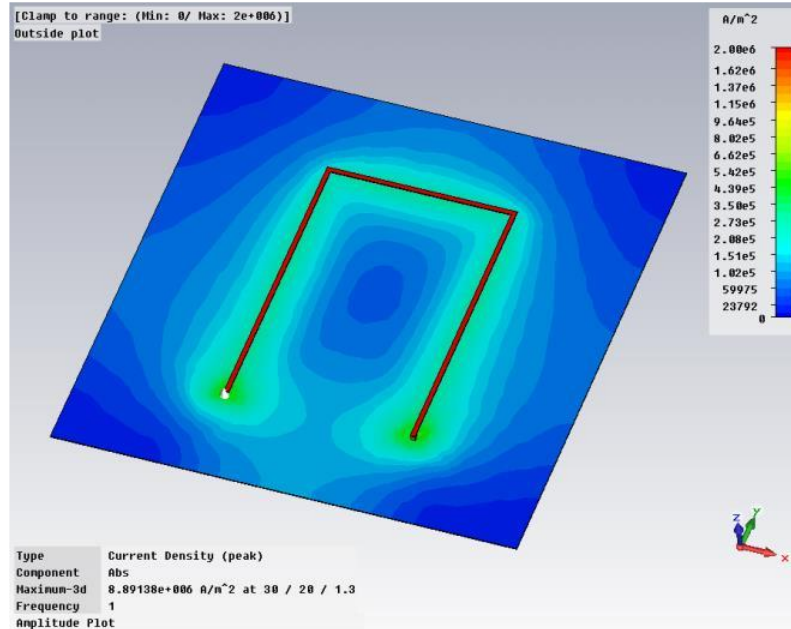
200 Hz



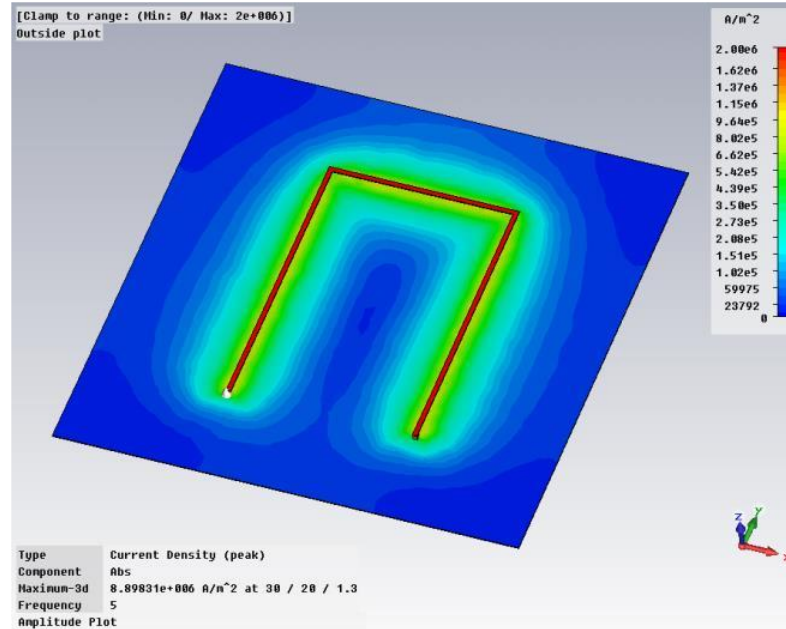
500 Hz

Path of least Impedance

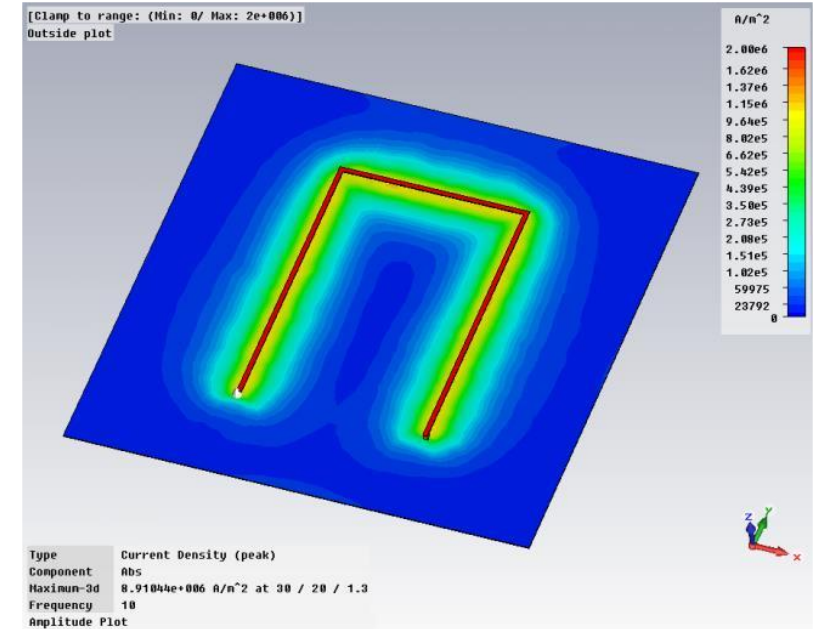
Simulation: Return Path depending on Frequency



1 kHz



2 kHz

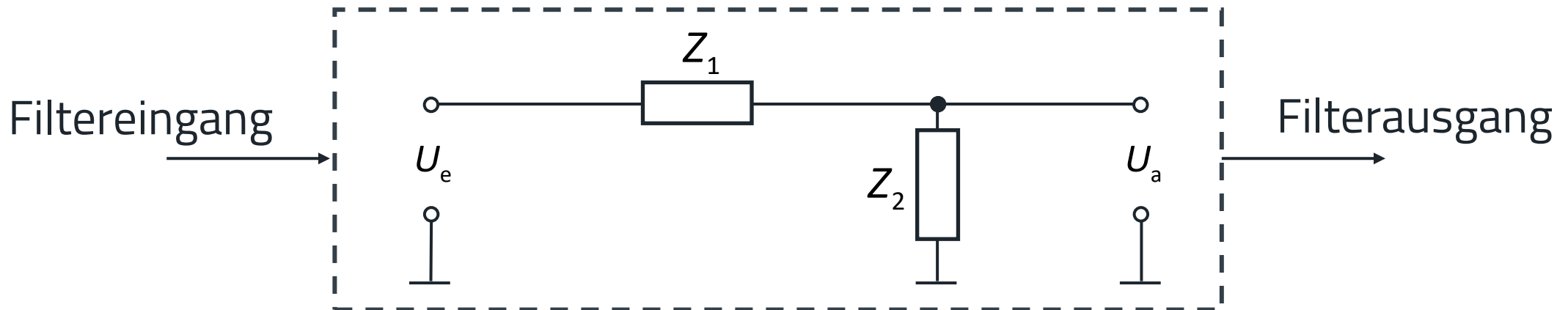


10 kHz

FILTERBAUTEILE

Prinzip der Filterung

- Definiertes Filter aus mindestens 2 Bauteilen
- mindestens ein Bauteil ist frequenzselektiv

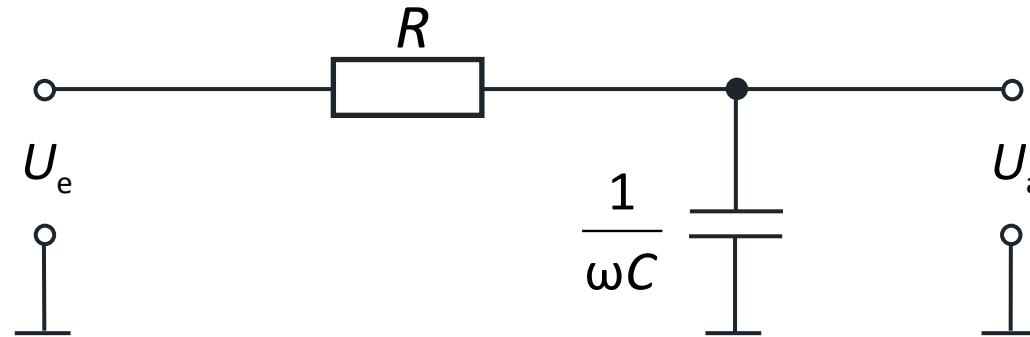


- Anpassung im Nutzfrequenzbereich
- Fehlanpassung im Störfrequenzbereich
- **Filter sind frequenzabhängige Spannungsteiler**

Der Tiefpass

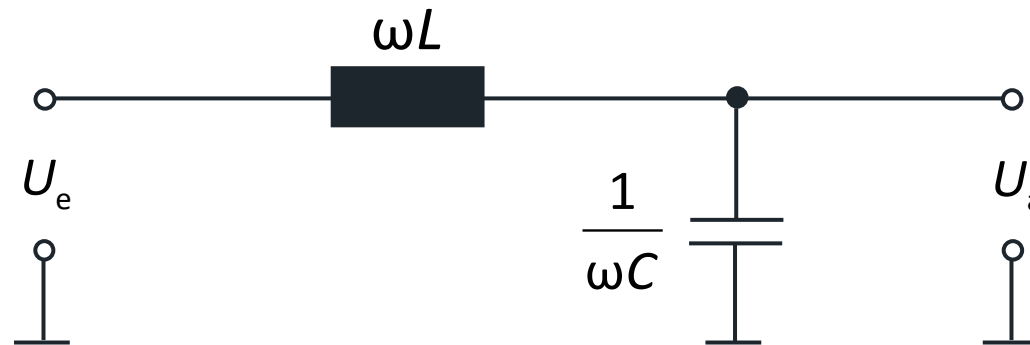
■ TP 1. Ordnung

- $f \uparrow \quad Z_C \downarrow$

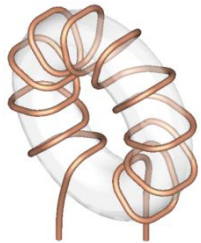


■ TP 2. Ordnung

- $f \uparrow \quad Z_C \downarrow$
- $f \uparrow \quad Z_L \uparrow$



Impedanz einer Ringspule mit Ferritkern



Air-coil impedance $\underline{Z}_0$



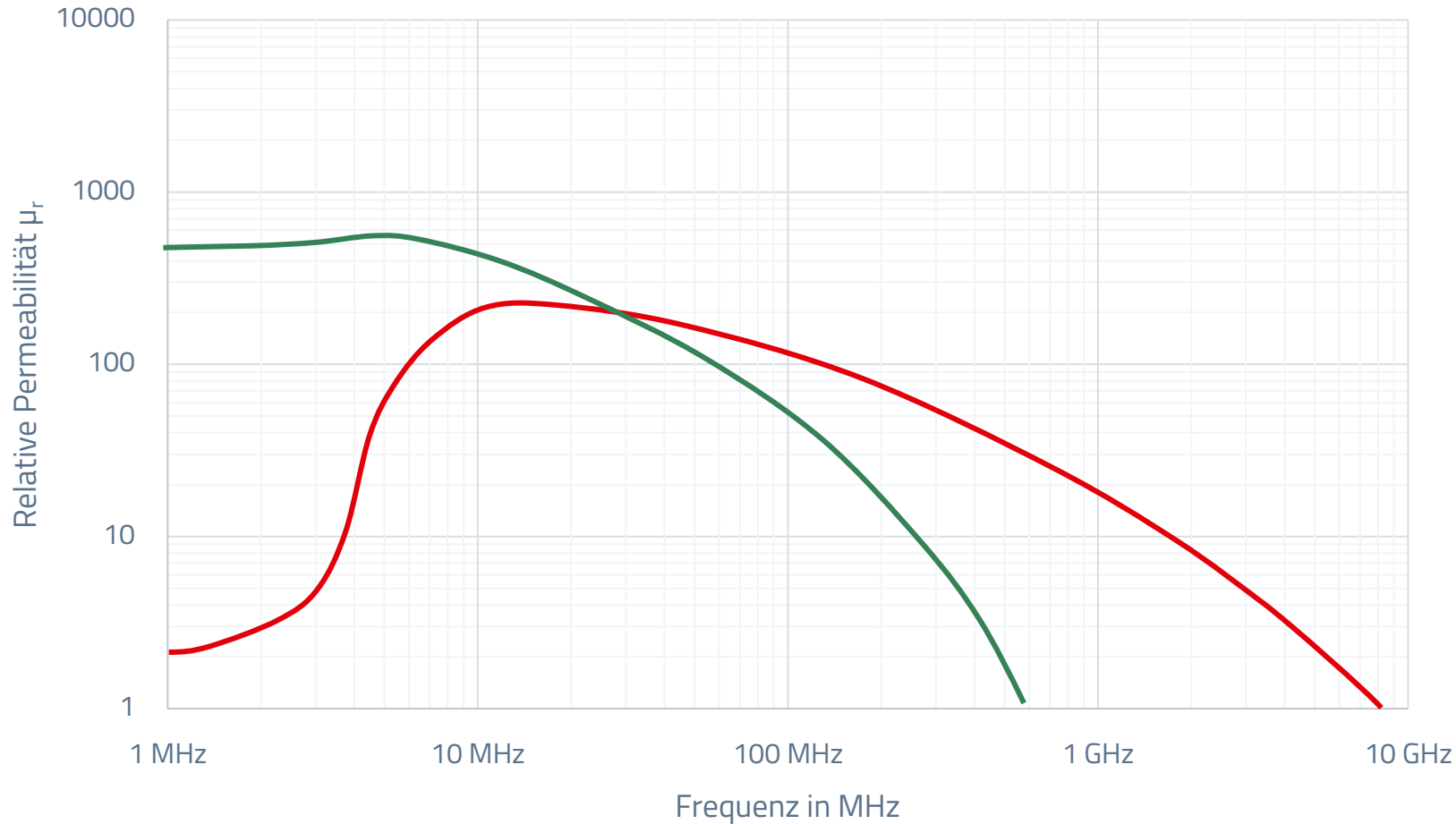
Ferrite permeability $\underline{\mu}_r$



$$\begin{aligned}\underline{Z}(f) &= \underline{Z}_0(f) \cdot \underline{\mu}_r(f) \\ &= j \cdot 2\pi \cdot f \cdot L_0 \cdot [\mu'_r(f) - j \cdot \mu''_r(f)] \\ &= j \cdot X_L(f) + R(f)\end{aligned}$$

Permeabilität

Frequenzabhängigkeit



$$\bar{\mu} = \mu' - j \mu''$$

$$\bar{Z} = j \omega L_0 * (\mu' - j \mu'')$$

$$\bar{Z} = R + j X_L$$

$$X_L = \omega L_0 \mu'$$

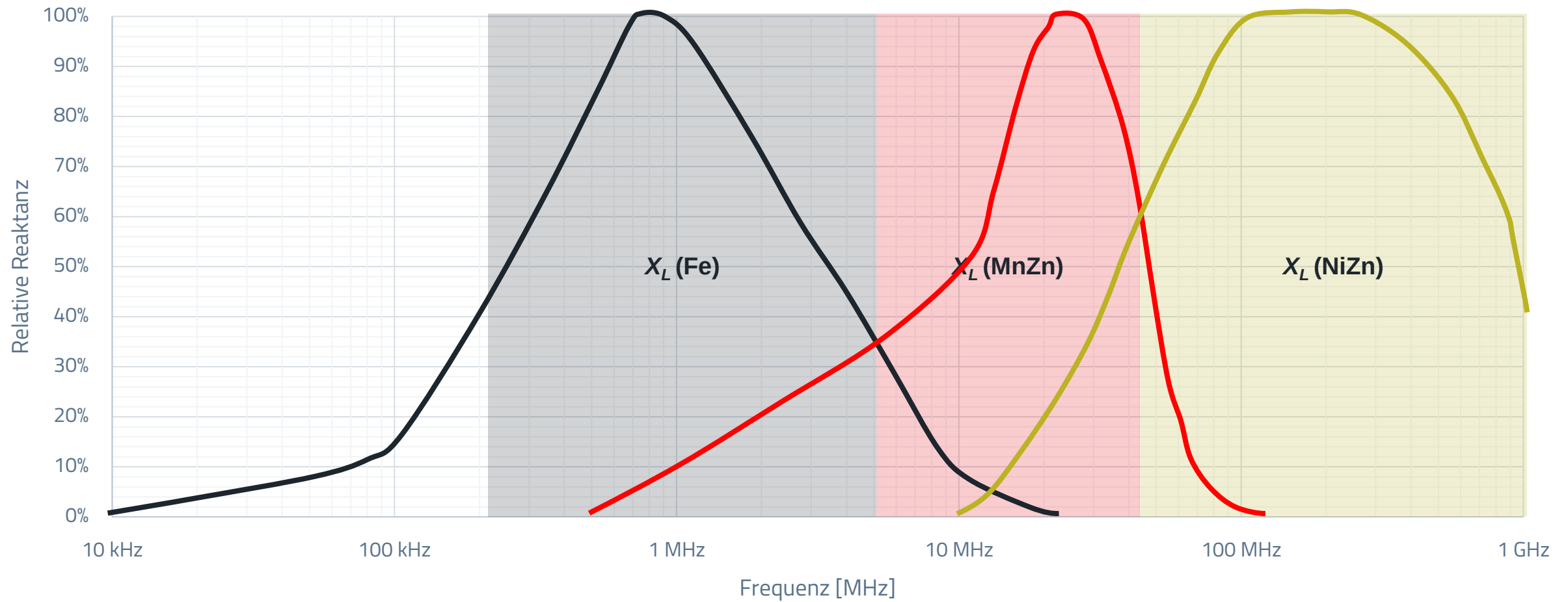
Frequenzabhängiger
Magnetisierungsanteil

$$R = \omega L_0 \mu''$$

Frequenzabhängiger Verlustanteil

Permeabilität

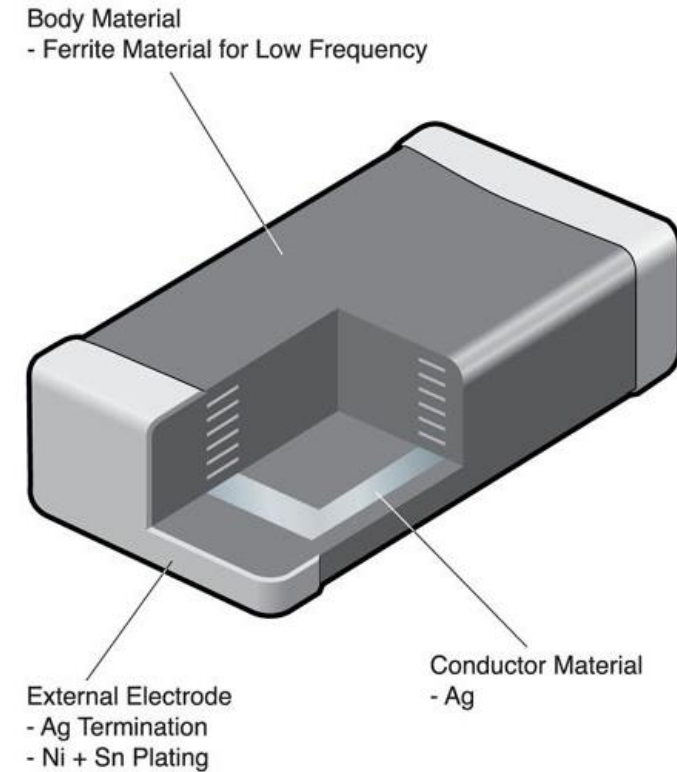
Verlustanteil



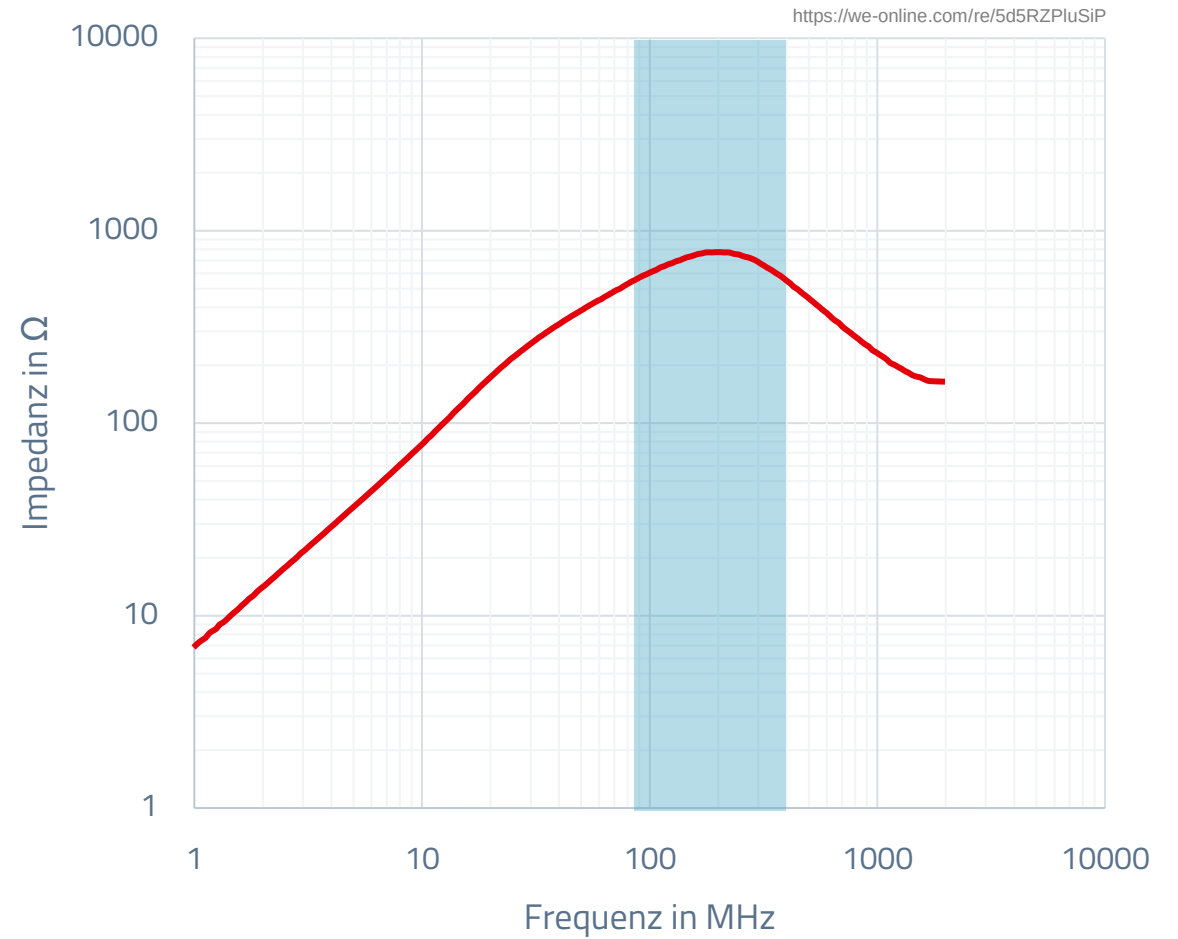
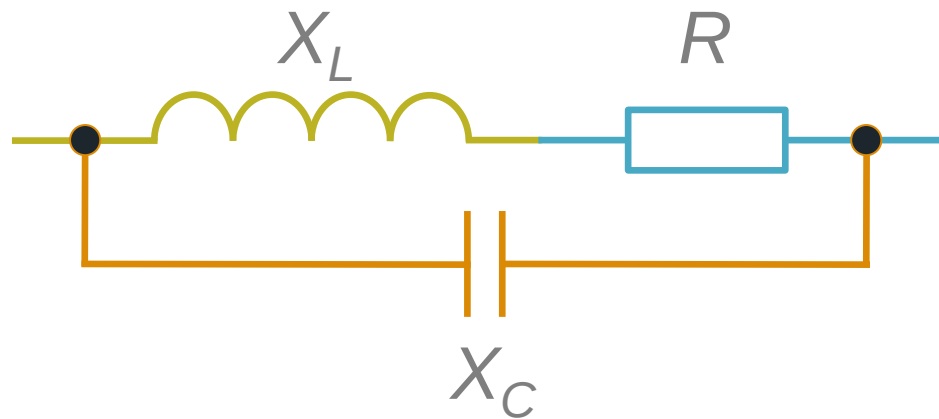
Aufbau Multilayer Ferrit



- als Ferritmaterial wird NiZn verwendet
- die Windungen in der Innenlage werden aus Silber im Siebdruckverfahren hergestellt
- Die Terminals bestehen aus Silber mit Nickel/Zinn Plating.



Frequenzverhalten eines Ferrits

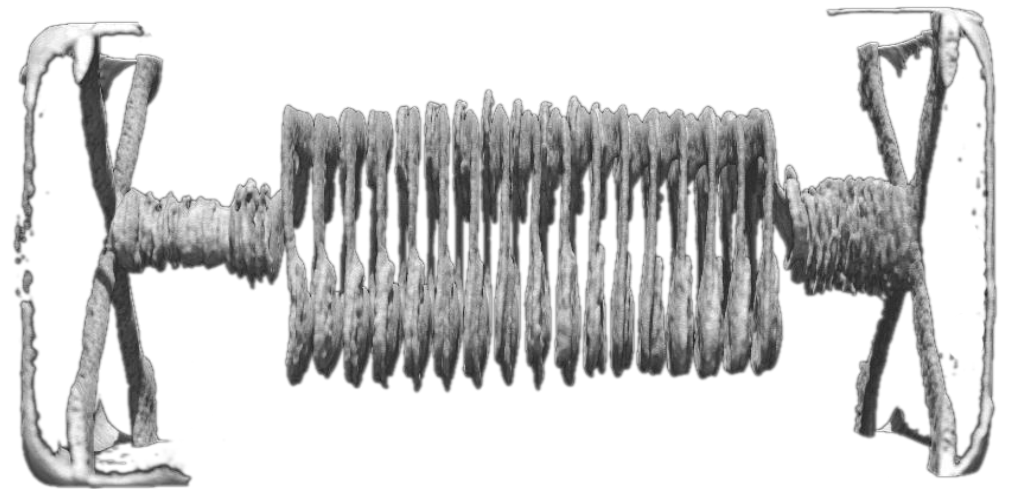


High Speed vs. Wideband

General Use vs. High Frequency



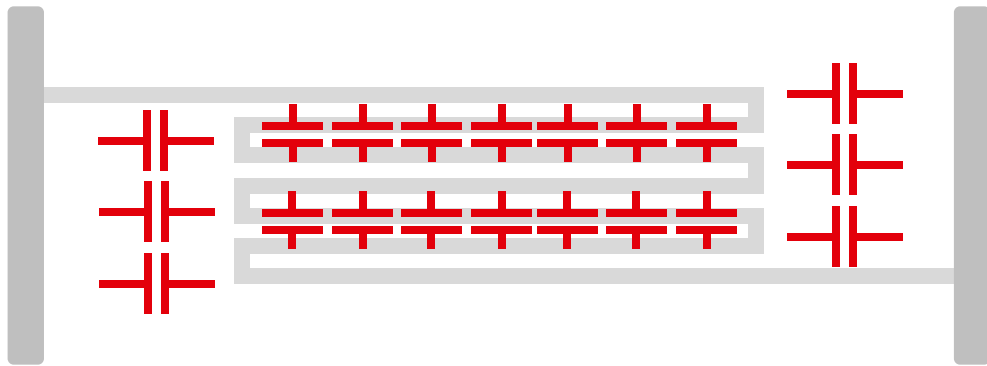
WE-CBF
Horizontale Anordnung der Lagen



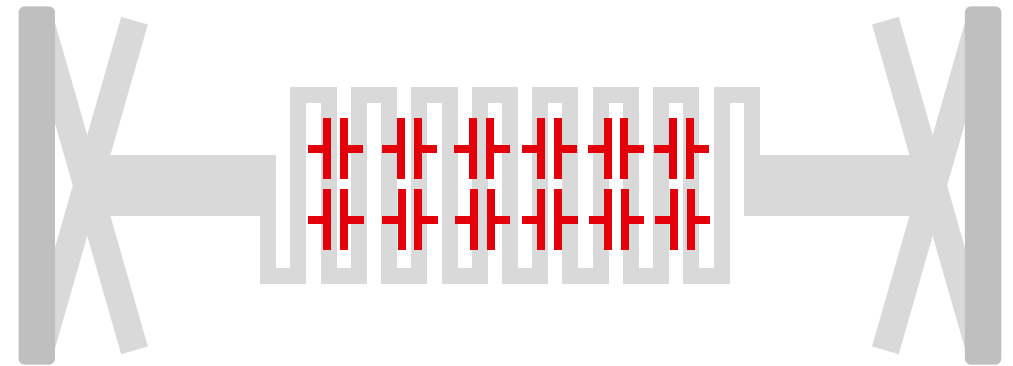
WE-CBF HF
Vertikale Anordnung der Lagen

General Use vs. High Frequency

$$\frac{1}{C_{sum}} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_n}$$

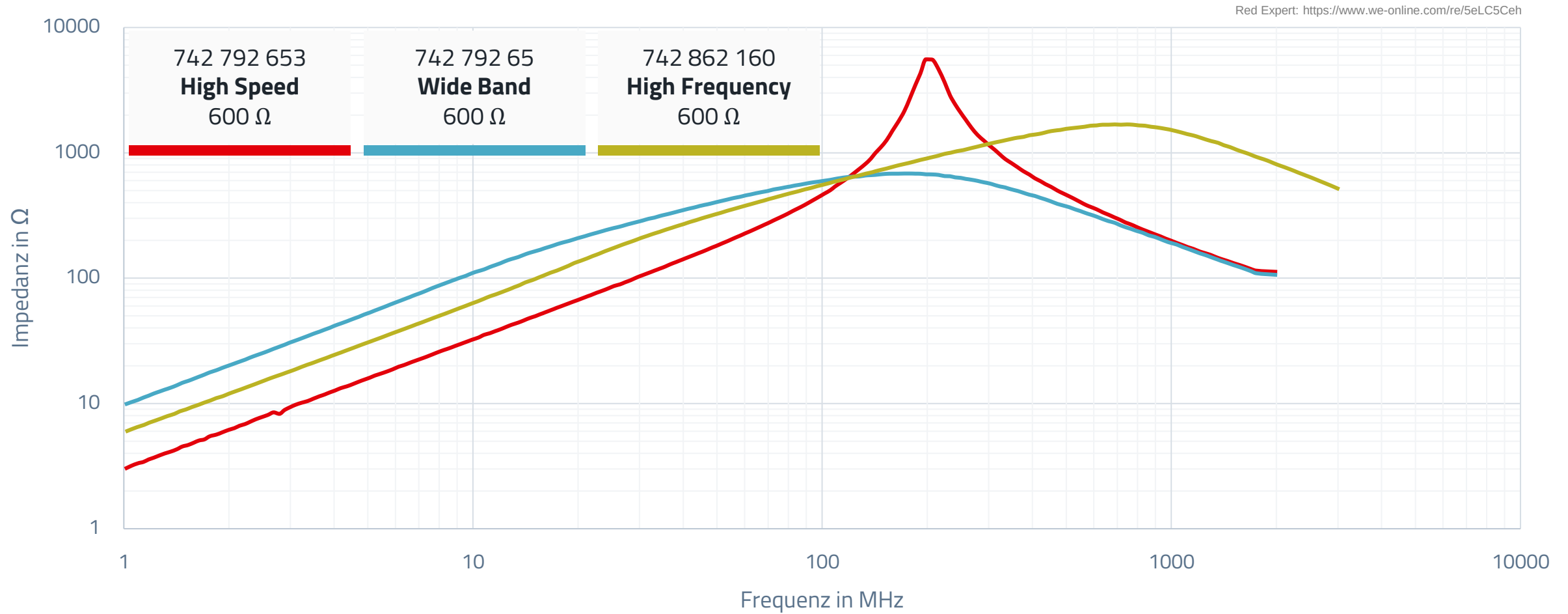


WE-CBF
Horizontale Anordnung der Lagen

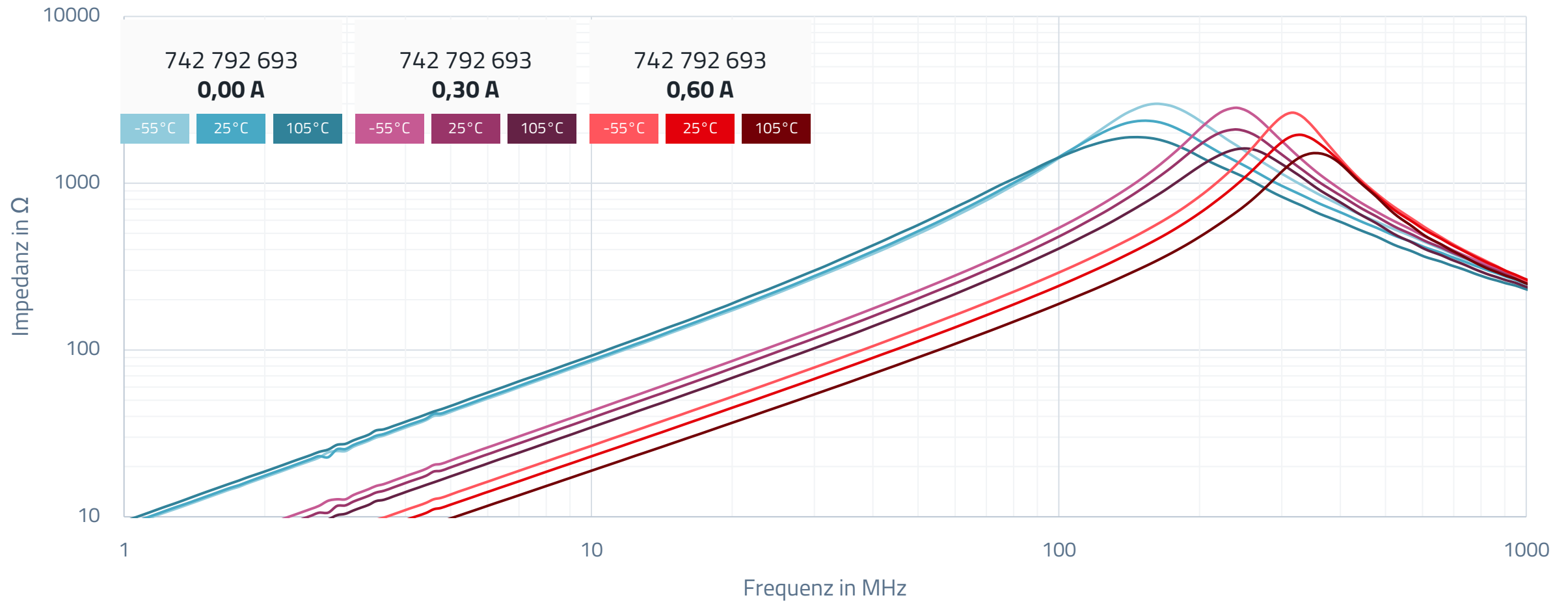


WE-CBF HF
Vertikale Anordnung der Lagen

Kategorien von SMD Ferriten



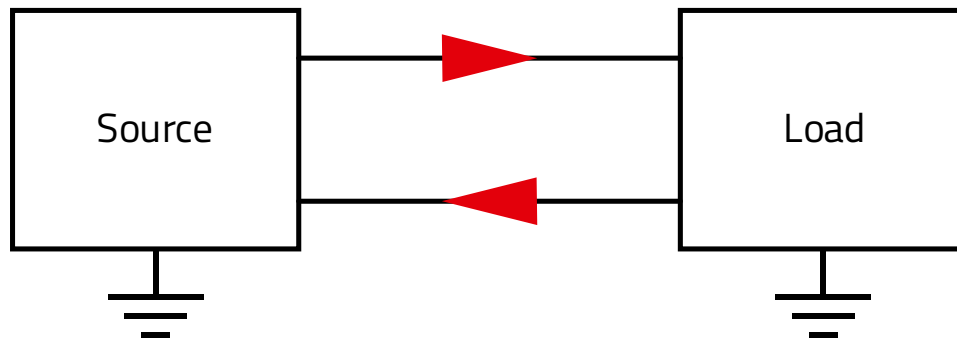
Verhalten der Impedanz unter Temperatur und Strom



GLEICHTAKT, GEGENTAKT

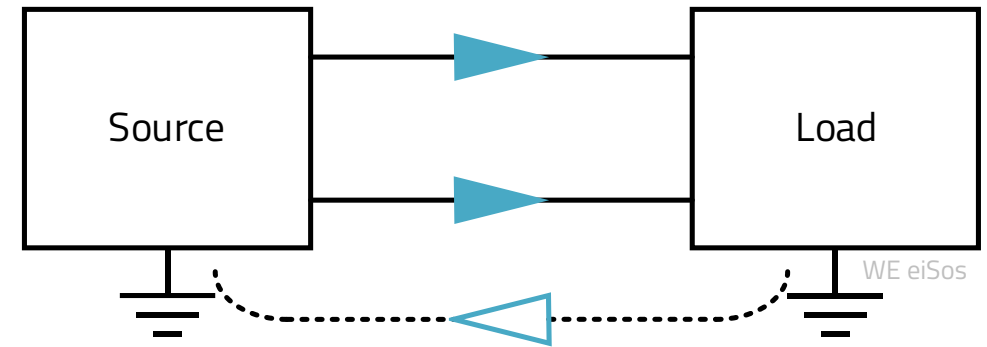
Noise Transmission Modes

Differential Mode



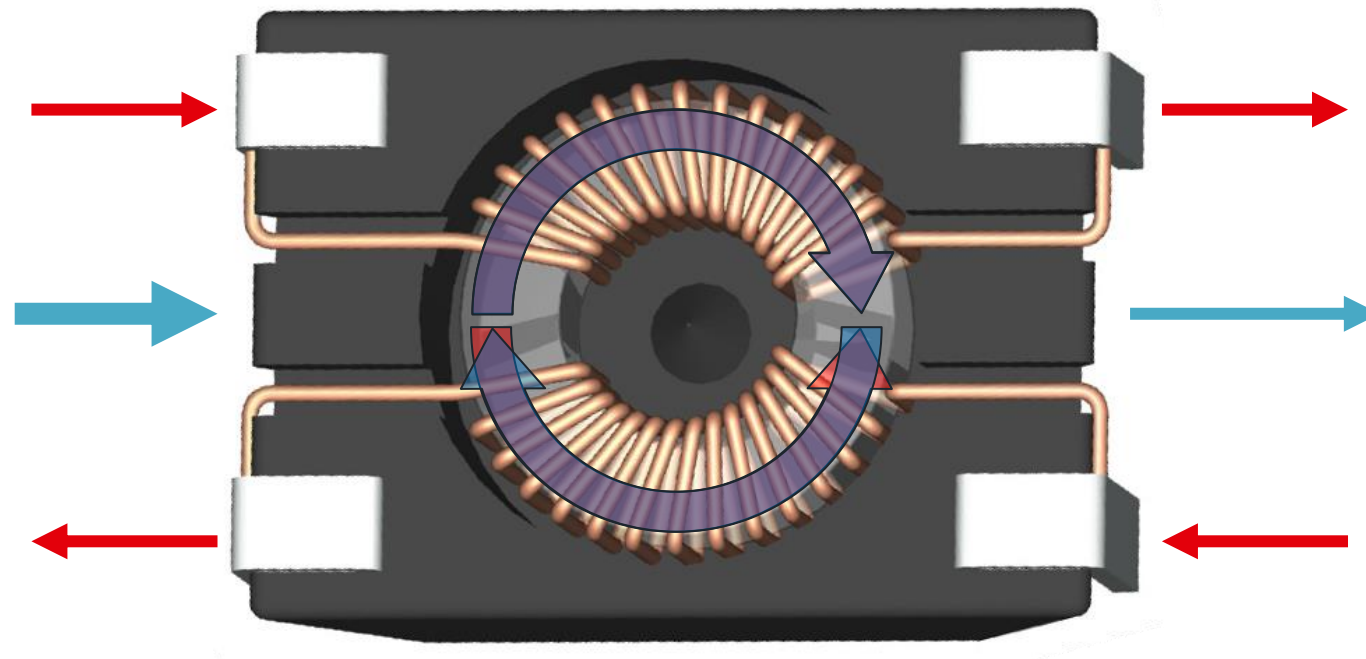
- Noise and useful signal use the same paths
- Earth is not affected

Common Mode



- Noise uses both lines in same direction
- Earth is used a return path

Common Mode Choke

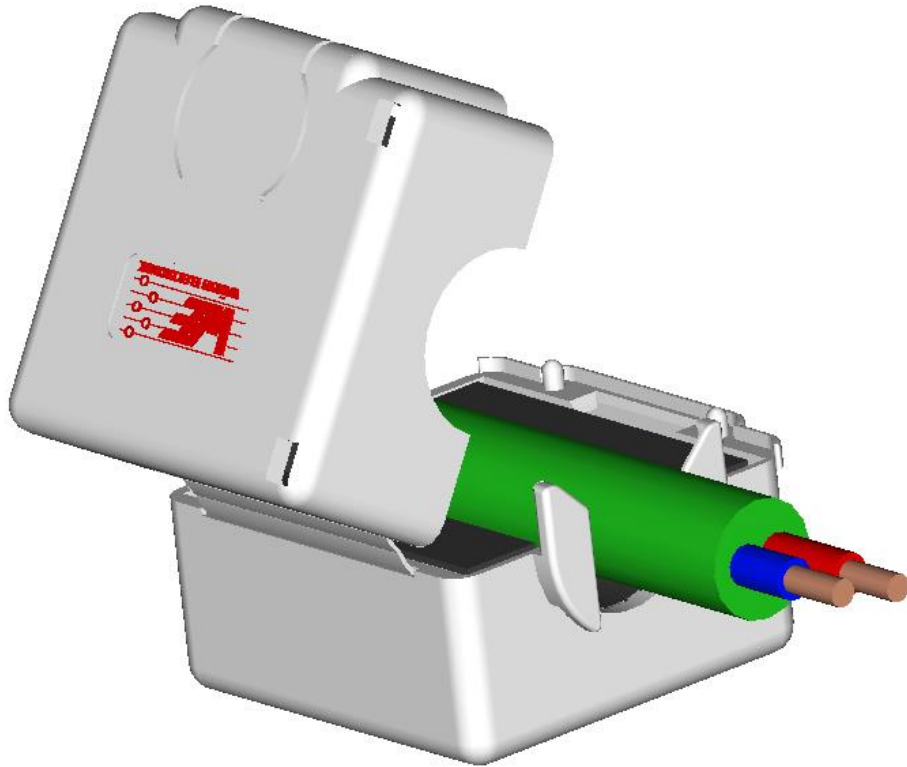


- **Compensation** of the **main magnetic flux** due to the differential-mode useful signal
- **Attenuation** of a **common-mode noise signal** by reflection and absorption

EXKURS: **RED**EXPERT



Stromkompensierte Drossel – Klappferrit



=
?
≠



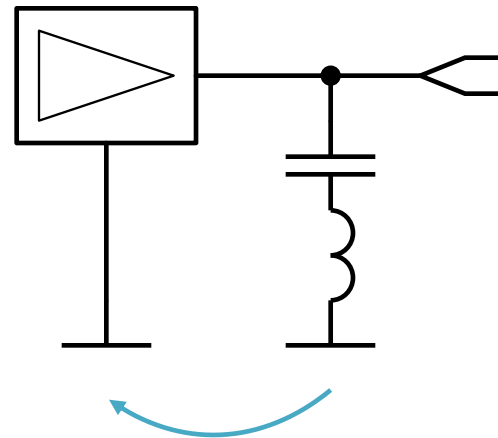
KONDENSATOREN

Filter Capacitors

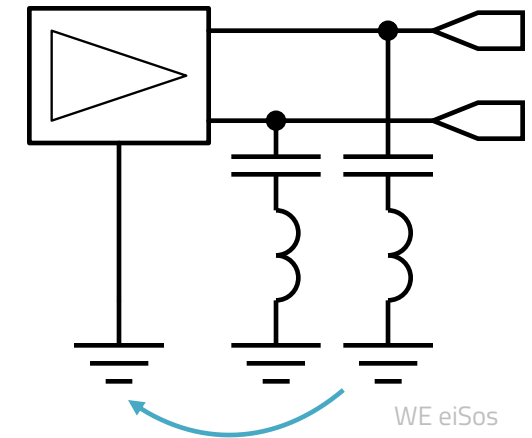
General Considerations

- For all capacitive Filters a low impedance connection to reference potential is key
 - For DM: (A/P) Ground
 - For CM: Earth / Chassis
- Additional Impedances decrease efficiency of RF short
 - THT contact pins
 - Inductance of PCB traces
 - Placement connection of steel spacers

Differential Mode Short



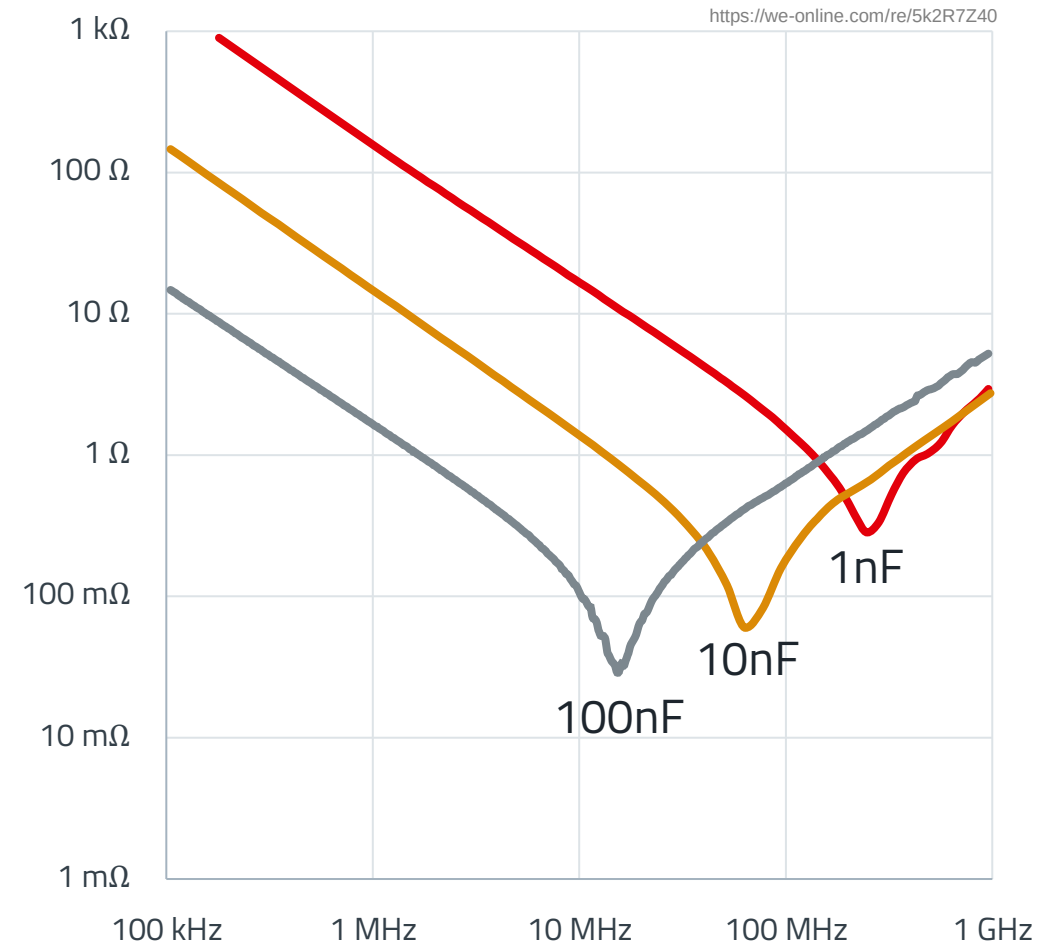
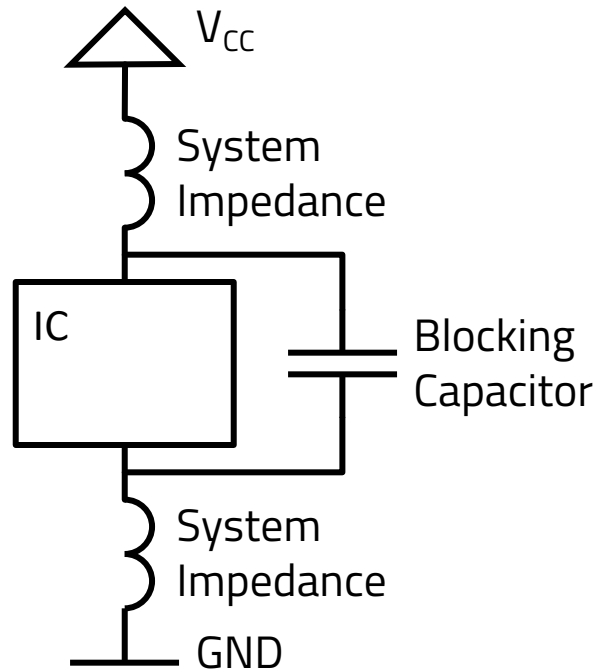
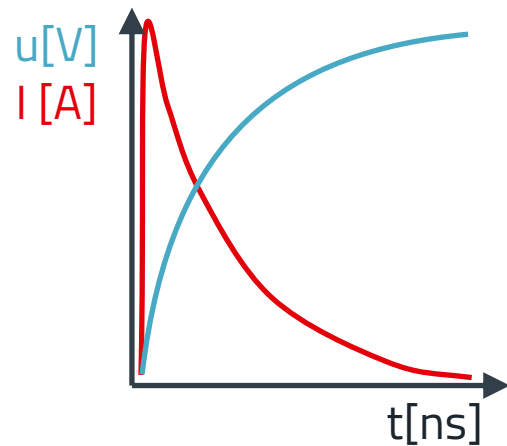
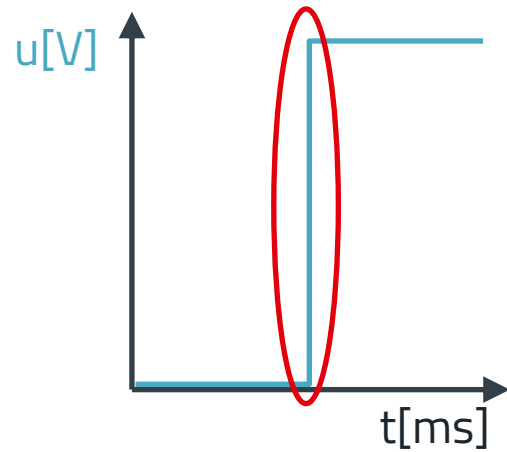
Common Mode Short



WE eiSos

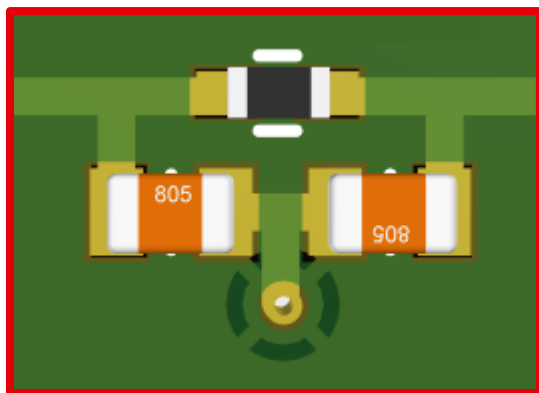
Blocking Capacitors

Mode of Operation and Selection Criteria

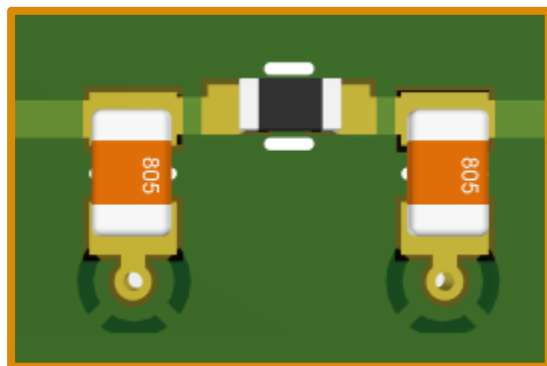


Filter Arrangement

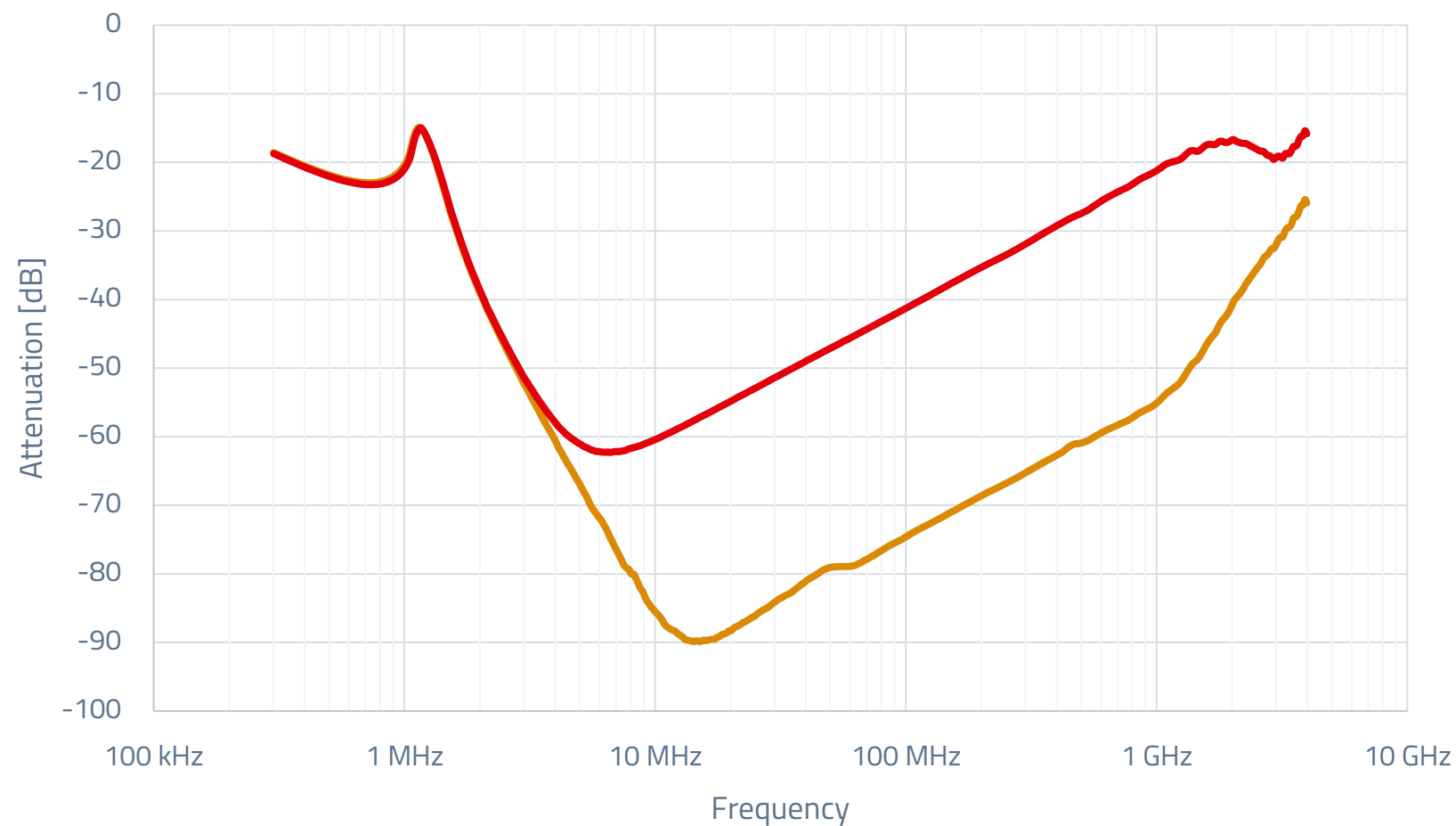
Layout: Influence on Insertion Loss



0805, Bad Layout



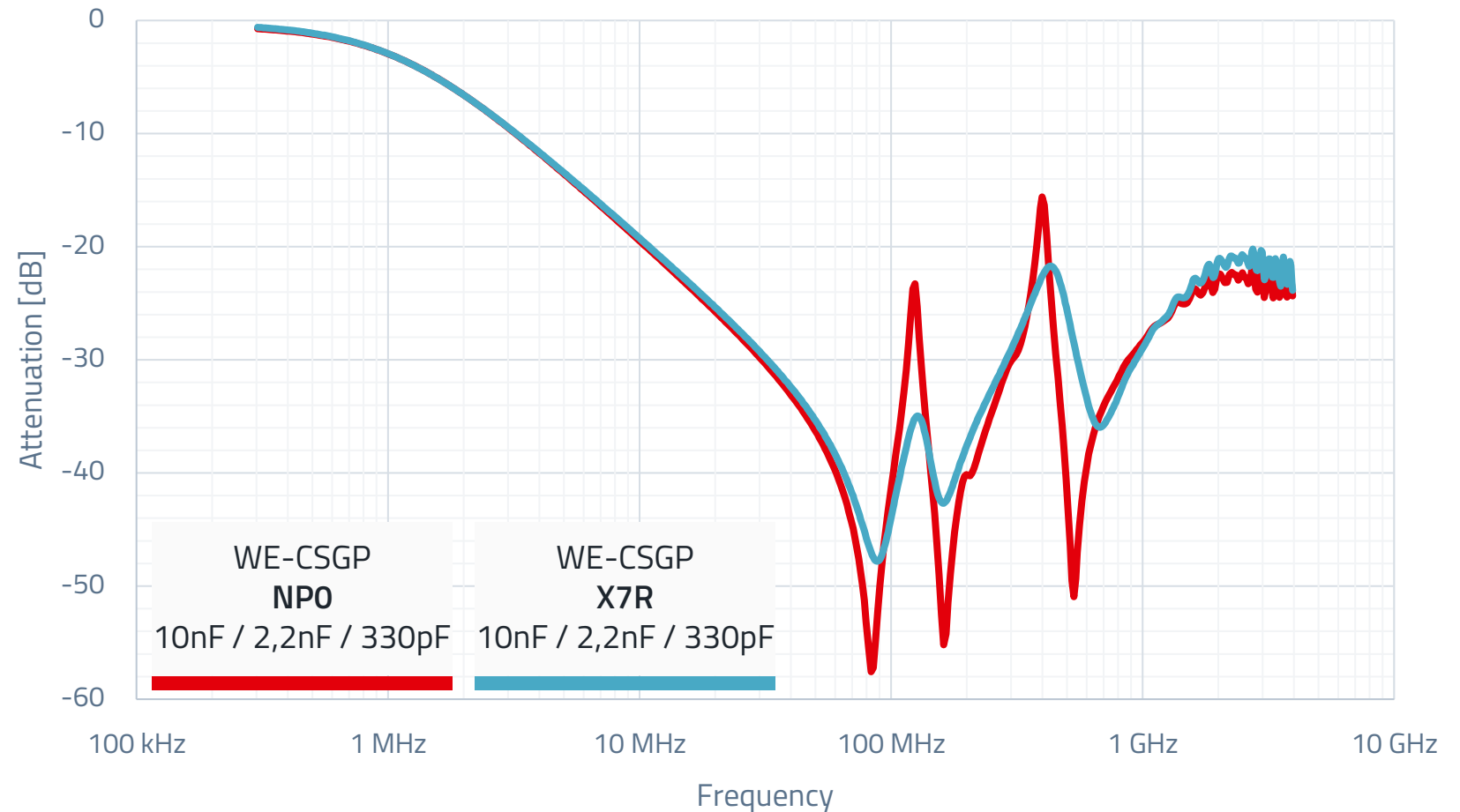
0805, Good Layout



Filter Capacitors

Selection Criteria

- Ceramic Class of the blocking capacitor affects performance
- NPO with high Q tends to resonate strongly
- X7R provides a smoother curve but has its downsides:
 - DC Bias
 - Temperature Stability
 - Aging



WIE FINDE ICH DEN RICHTIGEN FILTER?

Dimensioning of a filter choke

Impedance vs. Attenuation

- A filter choke in series connection forms a **first-order low-pass Filter**

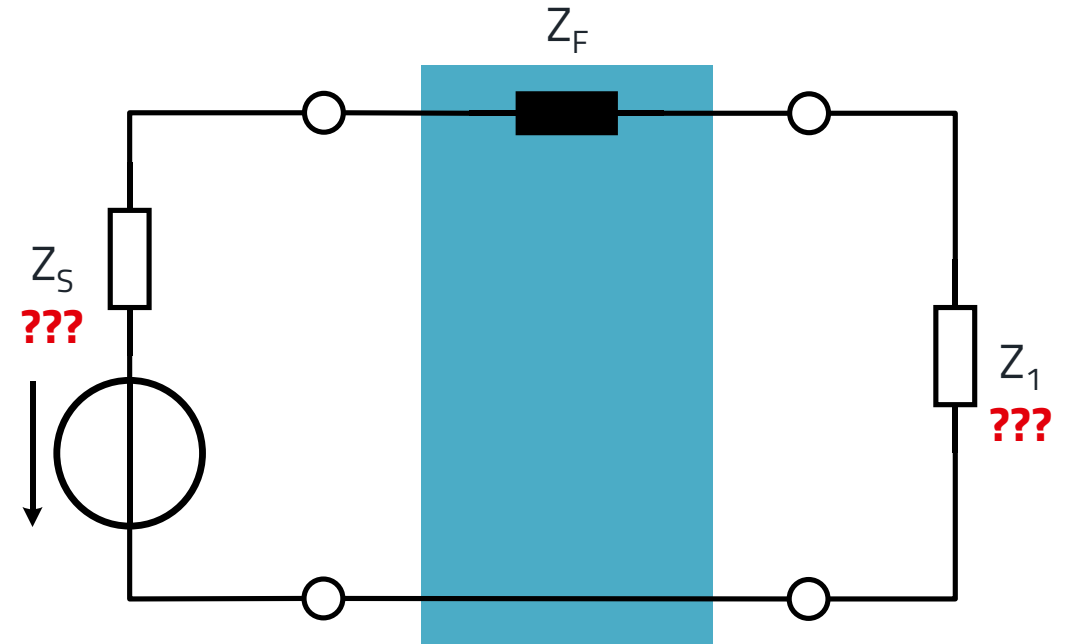
- **Insertion loss** in decibel:

$$A_{\text{dm}} = 20 \cdot \log \left| 1 + \frac{Z_F}{Z_s + Z_l} \right| \text{ dB}$$

- Minimum **filter impedance** at a noise frequency

$$Z_{\text{filter}} = |Z_s + Z_l|_{f_n} \cdot (10^{\frac{A_{\text{dm}}(f_n)}{20}} - 1)$$

- For an exact calculation the source and load impedance for each noise frequency would have to be known.



Dimensioning of a filter choke

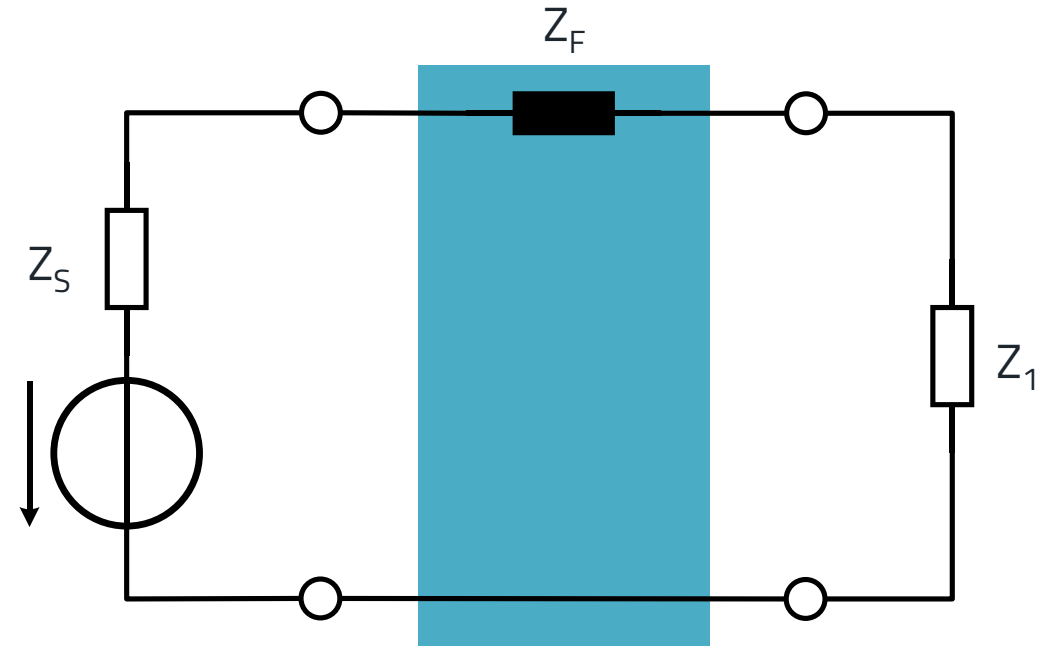
Impedance vs. Attenuation

- Minimum **filter impedance** at a noise frequency

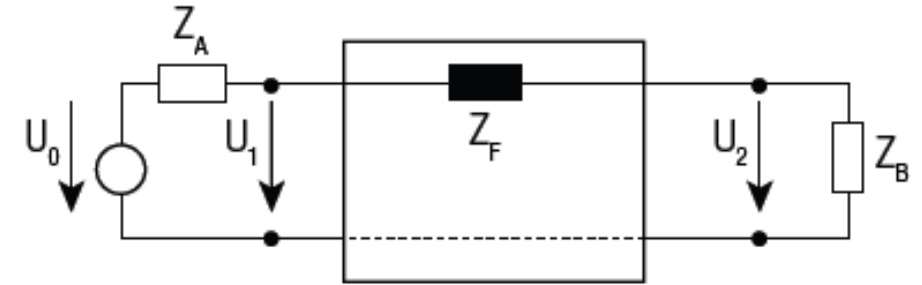
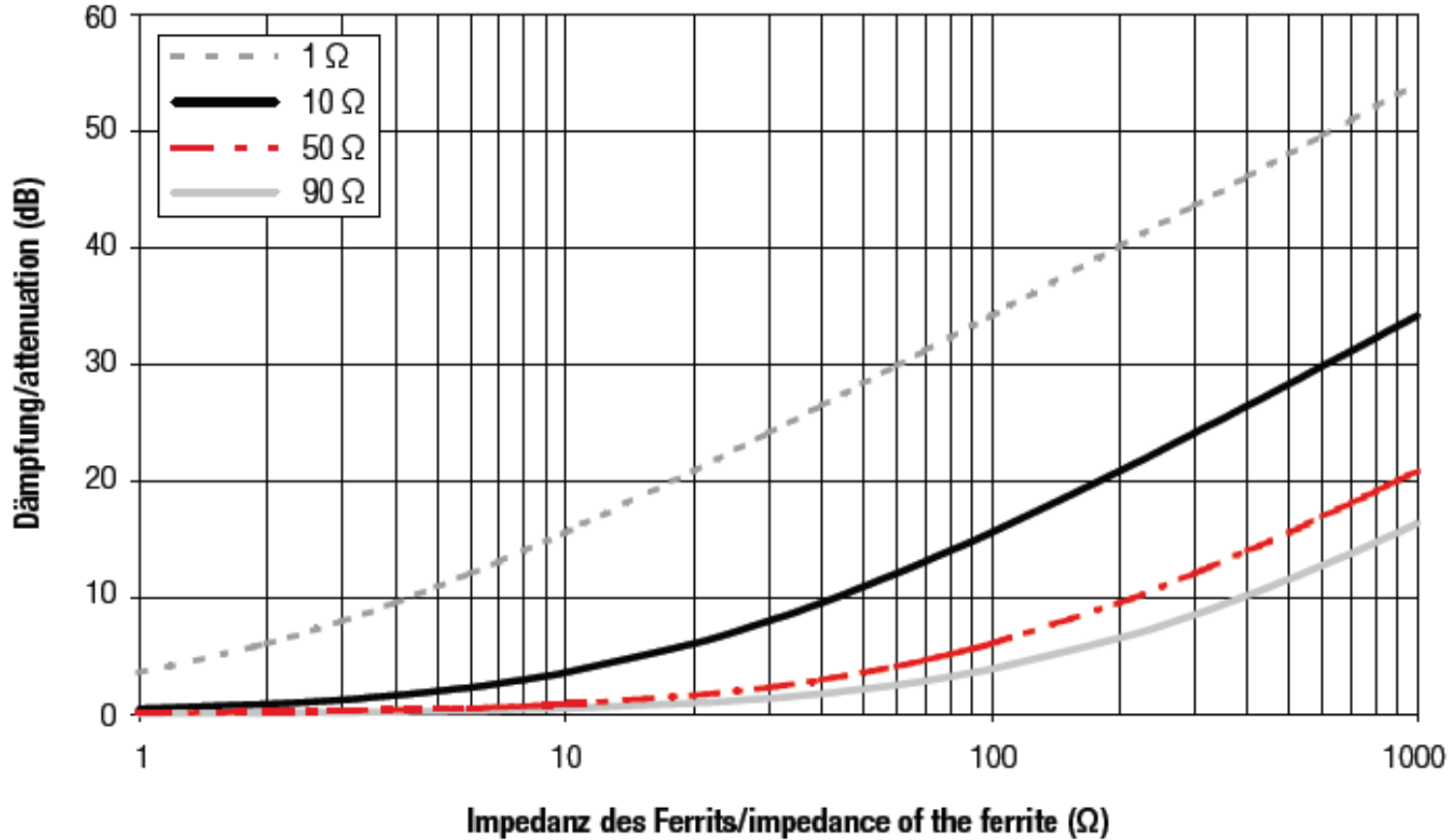
$$Z_{\text{filter}} = |Z_s + Z_l|_{f_n} \cdot \left(10^{\frac{A_{\text{dm}}(f_n)}{20}} - 1\right)$$

- Empirical Values for system impedances

- Ground 1 Ω
- Power Supply 10 Ω
- Clock-, Datalines 50...90 Ω
- Long Datalines 90...150 Ω



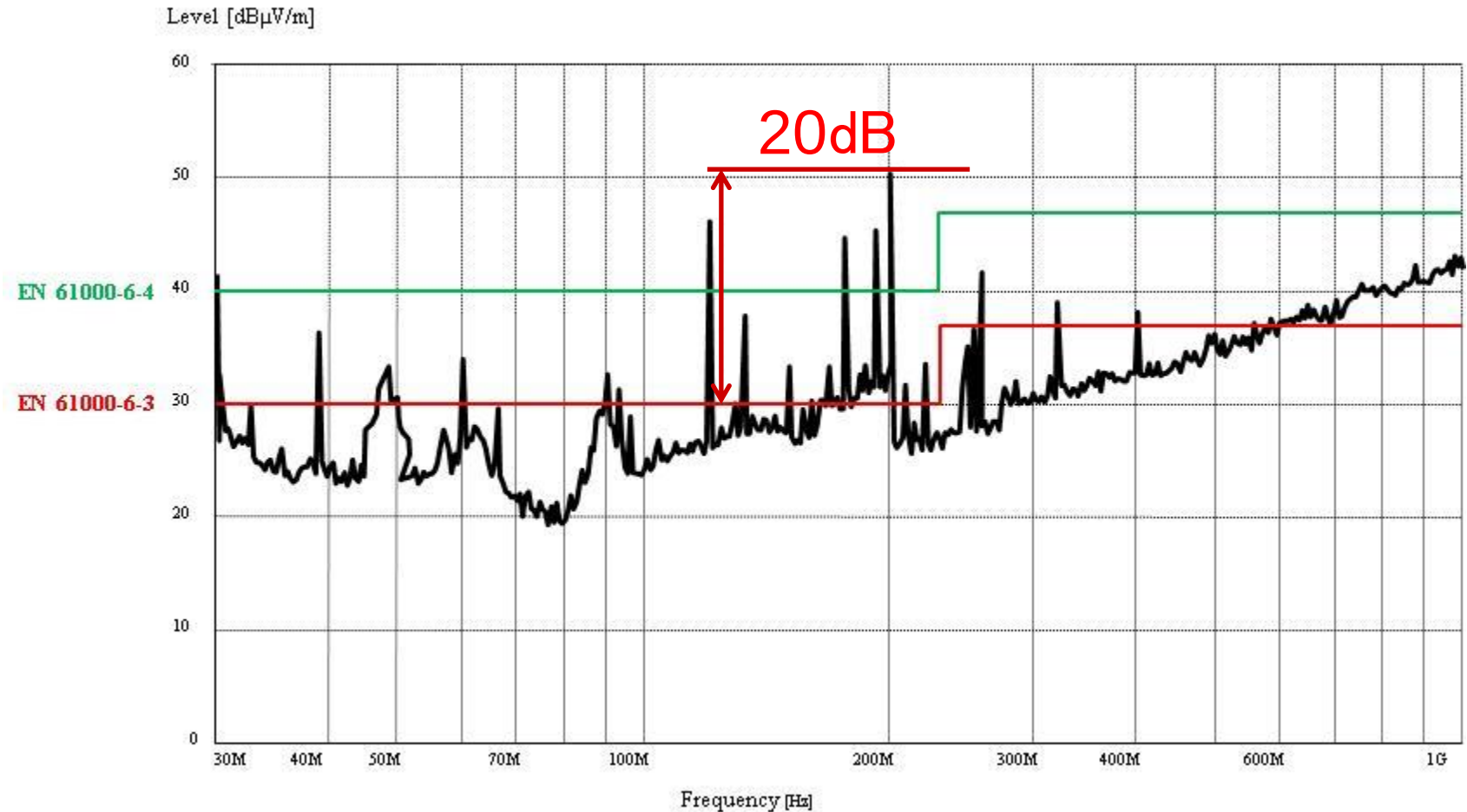
Nomogram



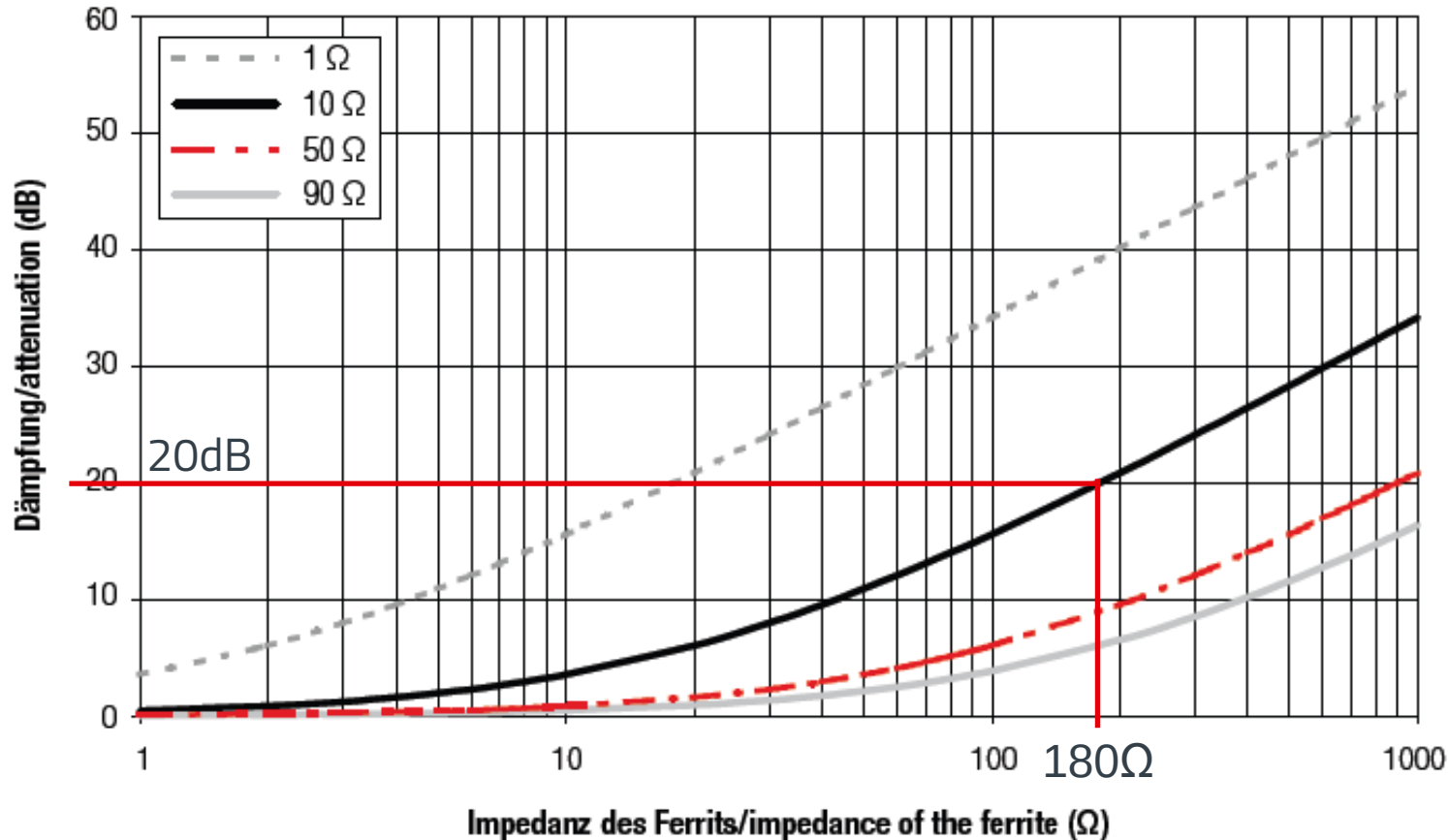
$$|A|_{dB} = 20 * \log_{10} \left(\frac{Z_A + Z_F + Z_B}{Z_A + Z_B} \right)$$

Auswahl eines Ferrits

- Stromversorgung mit 0,5A
- Einsatz im industriellen Umfeld
- EMV Test Ergebnis
 - Überhöhte Störausstrahlung
- Industrie
 - EN 61000-6-4
- Wohnbereich
 - EN 61000-6-3



Auswahl eines Ferrits - Katalog



Anwendungsübersicht

System-Impedanz	Anwendung
1 Ω	GND
10 Ω	V _{cc} Spannungsversorgung
50 Ω – 90 Ω	Datenleitungen: Videosignal, Takt, USB
90 Ω – 150 Ω	„lange“ Datenleitungen

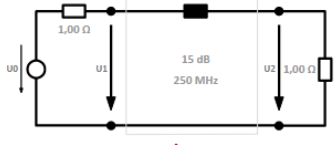


Auswahl eines Ferrits - Redexpert



Quell- / Senken-System

PARAMETER



Anwendungs-Tipps

- Lange Datenleitungen: 120 Ω
- Daten- und Signalleitungen: 70 Ω
- Stromversorungen (V_{CC}): 15 Ω
- Masseflächen (GND): 1 Ω
- benutzerdefiniert

Einfügedämpfung

Att 15 dB f 250 MHz

Quelle (Z_A)

Z 1 Ω

Senke (Z_B)

Z 1 Ω

Details Anzeigen

Filter: Z @250 MHz ≥ 9,25 Ω

Artikel-Nr.	Serie	Bauform	Spez	Typ	Z	Z @250 MHz	Att @250 MHz	Z _{max}	R _{DC}
742792035	WE-CBF	0805	PDF	High Speed	300 Ω @100 MHz	432 Ω	46,7 dB	450 Ω @220 MHz	300 mΩ
742792021	WE-CBF	0805	PDF	High Current	22,0 Ω @100 MHz	30,2 Ω	24,1 dB	40,0 Ω @1,00 GHz	8,00 mΩ
74279228111	WE-MPSB	0603	PDF	High Current	110 Ω @100 MHz	134 Ω	36,7 dB	135 Ω @226 MHz	14,5 mΩ
74279267	WE-CBF	0603	PDF	High Speed	60,0 Ω @100 MHz	81,5 Ω	32,4 dB	110 Ω @650 MHz	300 mΩ
74279220800	WE-MPSB	0805	PDF	High Current	80,0 Ω @100 MHz	102 Ω	34,3 dB	120 Ω @662 MHz	13,0 mΩ
74279220181	WE-MPSB	0805	PDF	High Current	180 Ω @100 MHz	184 Ω	39,4 dB	202 Ω @155 MHz	26,5 mΩ
74279220321	WE-MPSB	0805	PDF	High Current	320 Ω @100 MHz	321 Ω	44,2 dB	347 Ω @170 MHz	30,5 mΩ

74279228111 WE-MPSB 0603 110 Ω @100 MHz

742792021 WE-CBF 0805 22,0 Ω @100 MHz

742792035 WE-CBF 0805 300 Ω @100 MHz

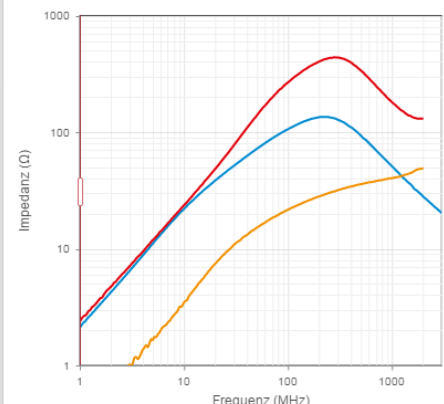
Zum Hinzufügen die Artikel hier platzieren

Muster ordern

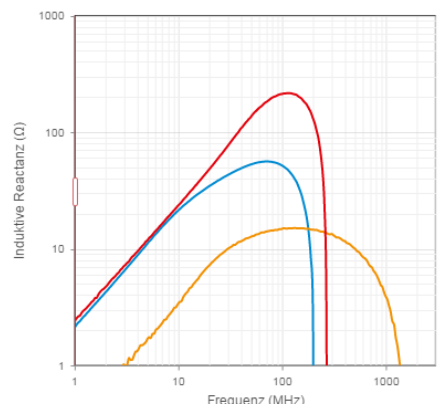
Aufräumen

Grafiken: Z vs. F X vs. F R vs. F I vs. L I vs. N

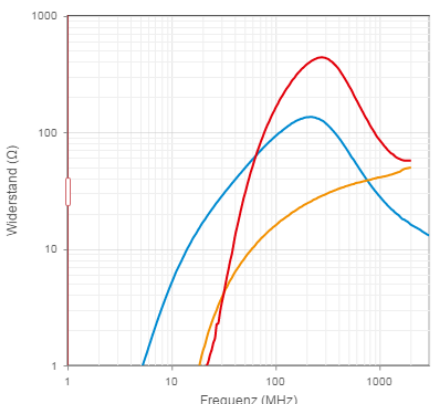
Impedanz / Frequenz



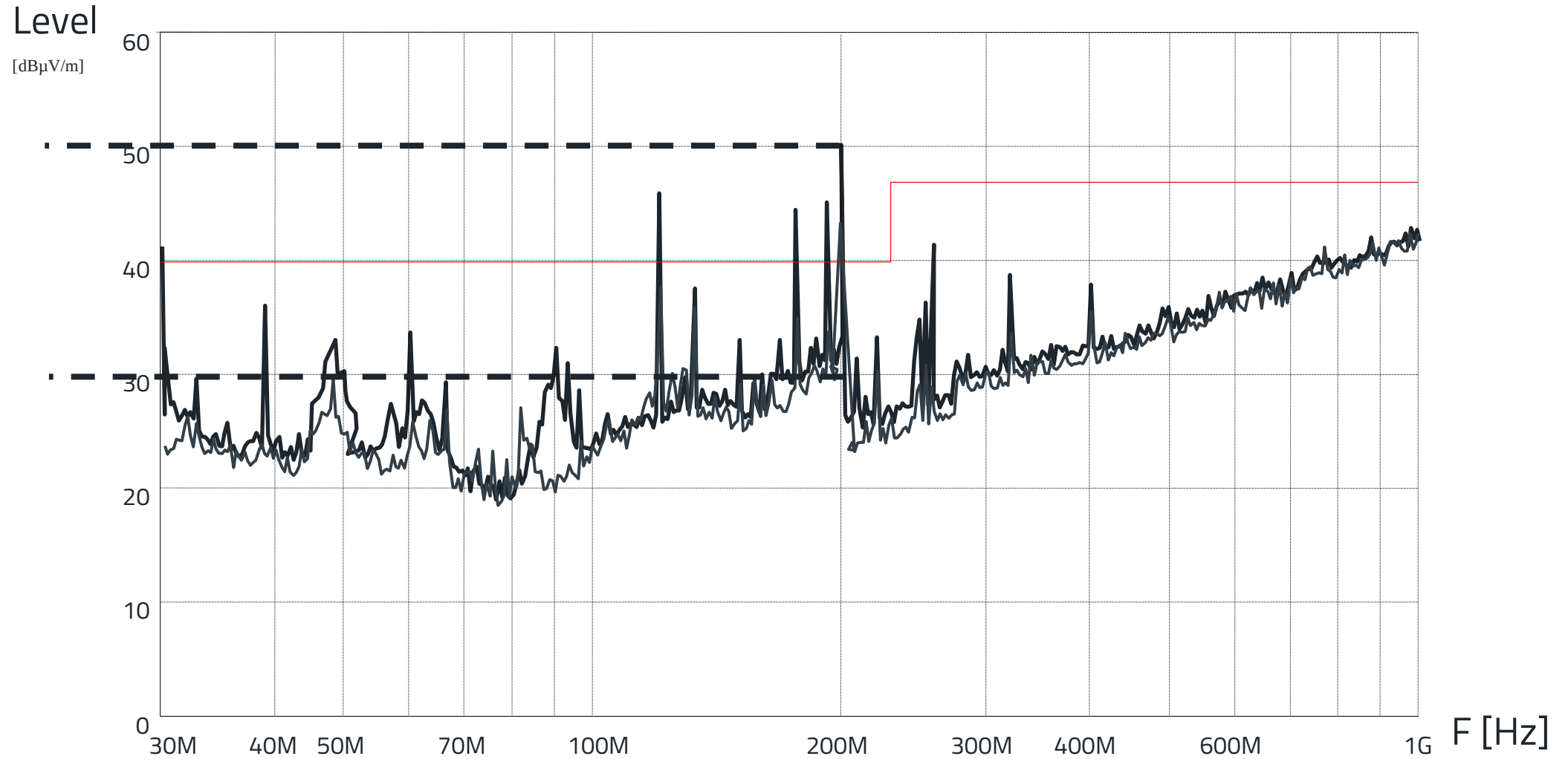
Reaktanz / Frequenz



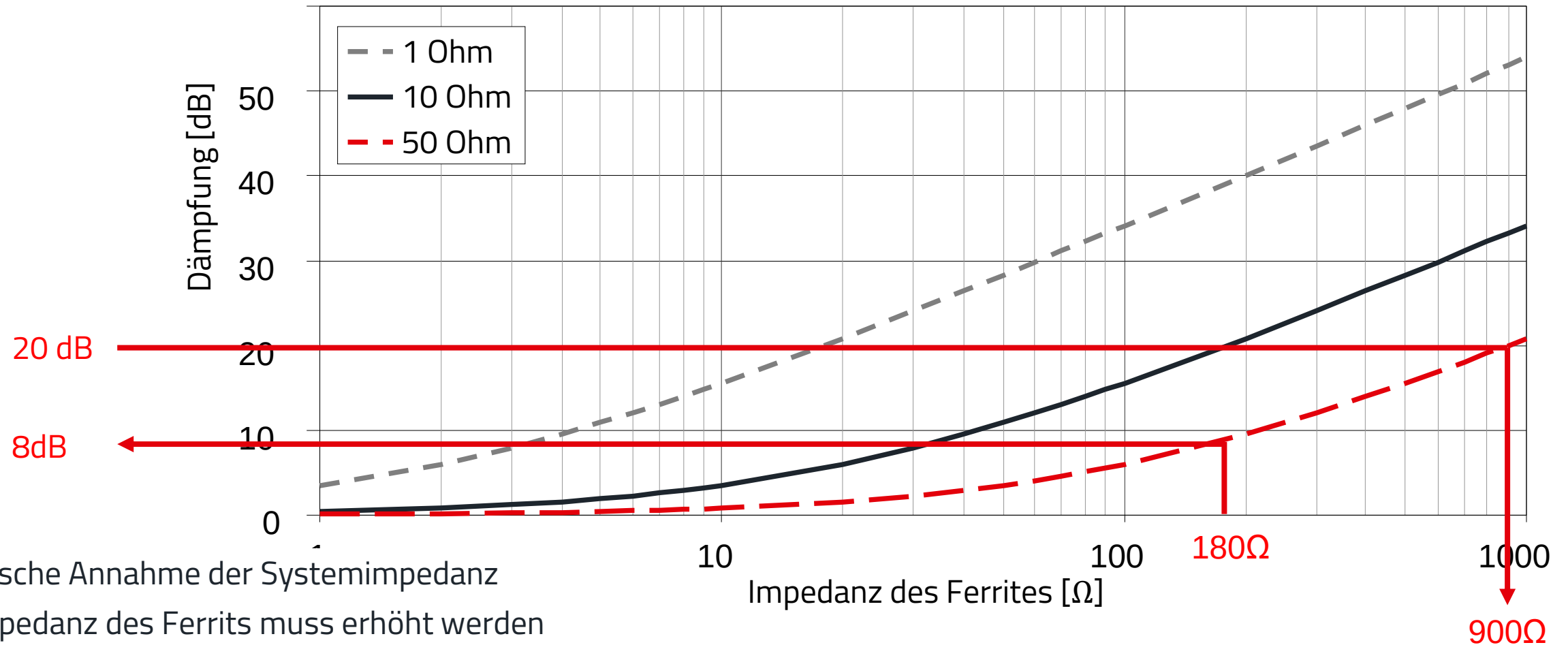
Widerstand / Frequenz



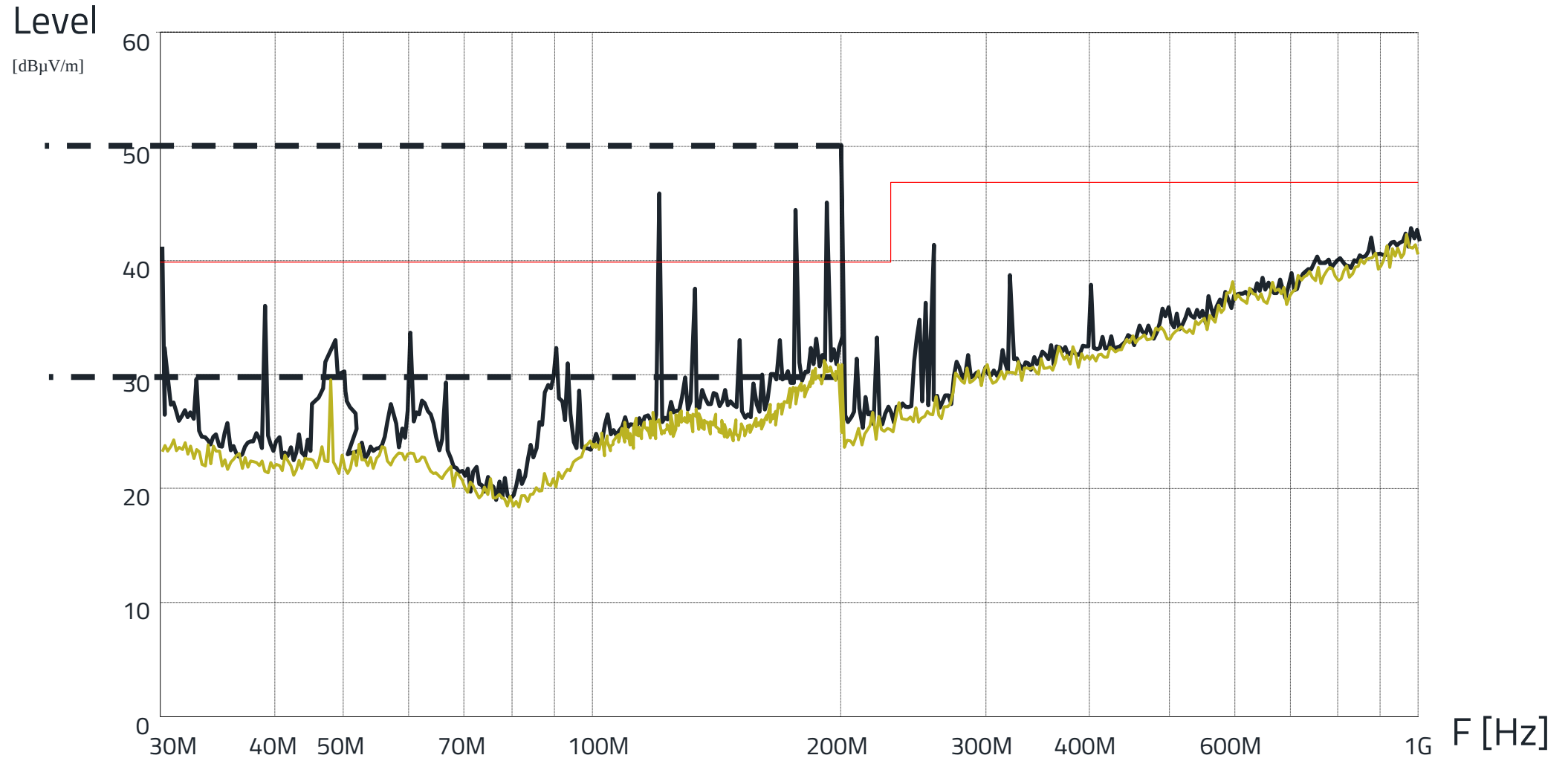
Einfügedämpfung – Beispiel



Einfügedämpfung – zu niedrig



Einfügedämpfung – Beispiel



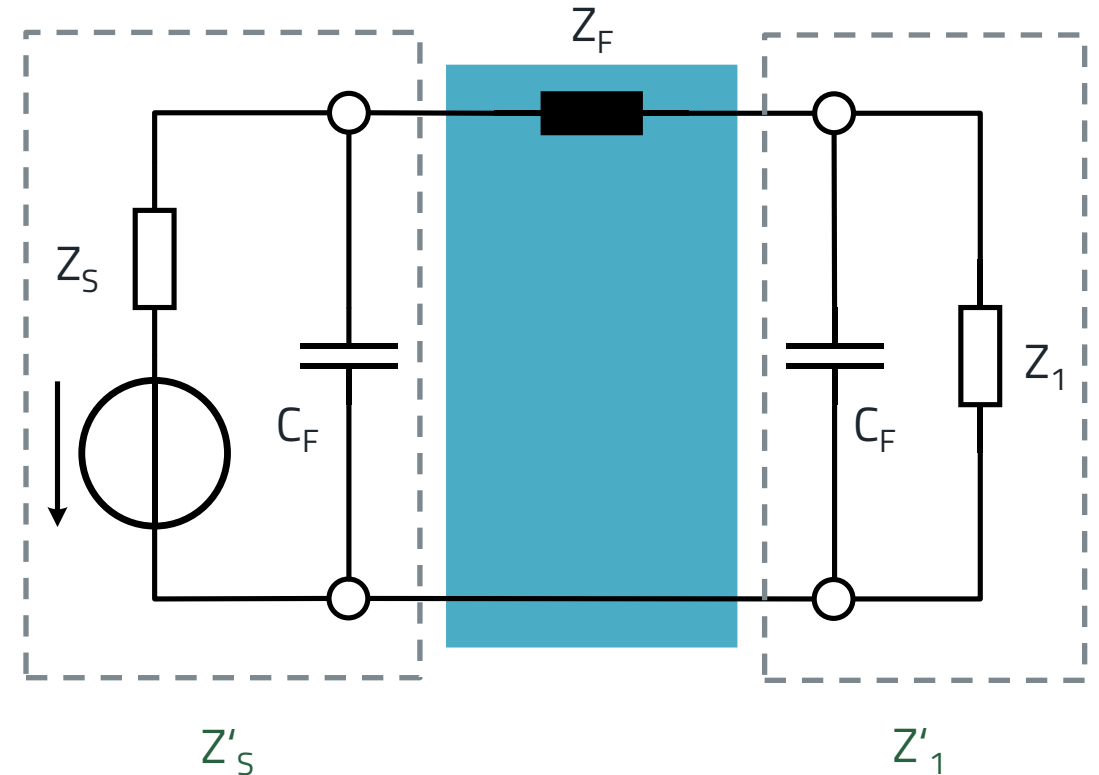
Dimensioning of a Filter

Adjusting the Operating Point with Capacitors

- Parallel Capacitors decrease System Impedance

$$A_{\text{dm}} = 20 \cdot \log \left| 1 + \frac{Z_F}{Z'_s + Z'_l} \right| \text{dB}$$

- Caps will also work as an RF Short to Ground
- Pay Attention to SRF of the Components
- 2nd order Filter Topologies can be adjusted to system impedances



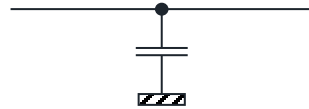
Empfohlene Topologien

Quellen- Impedanz

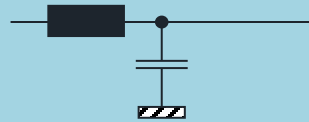
niedrig



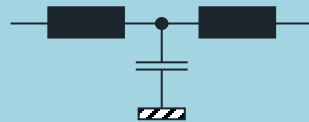
hoch



niedrig



unbekannt/
niedrig



unbekannt/
hoch



Senken- Impedanz

niedrig

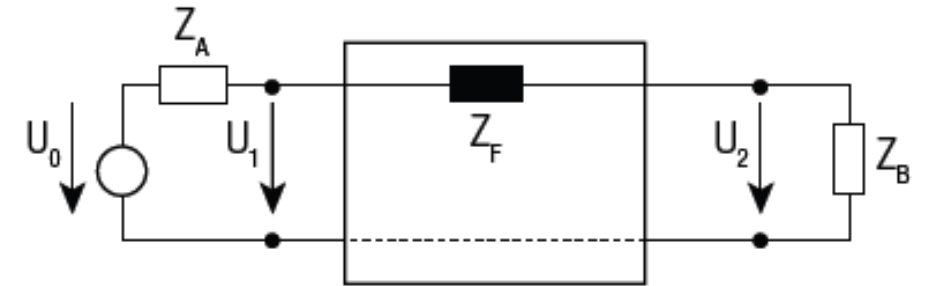
hoch

hoch

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niedrig

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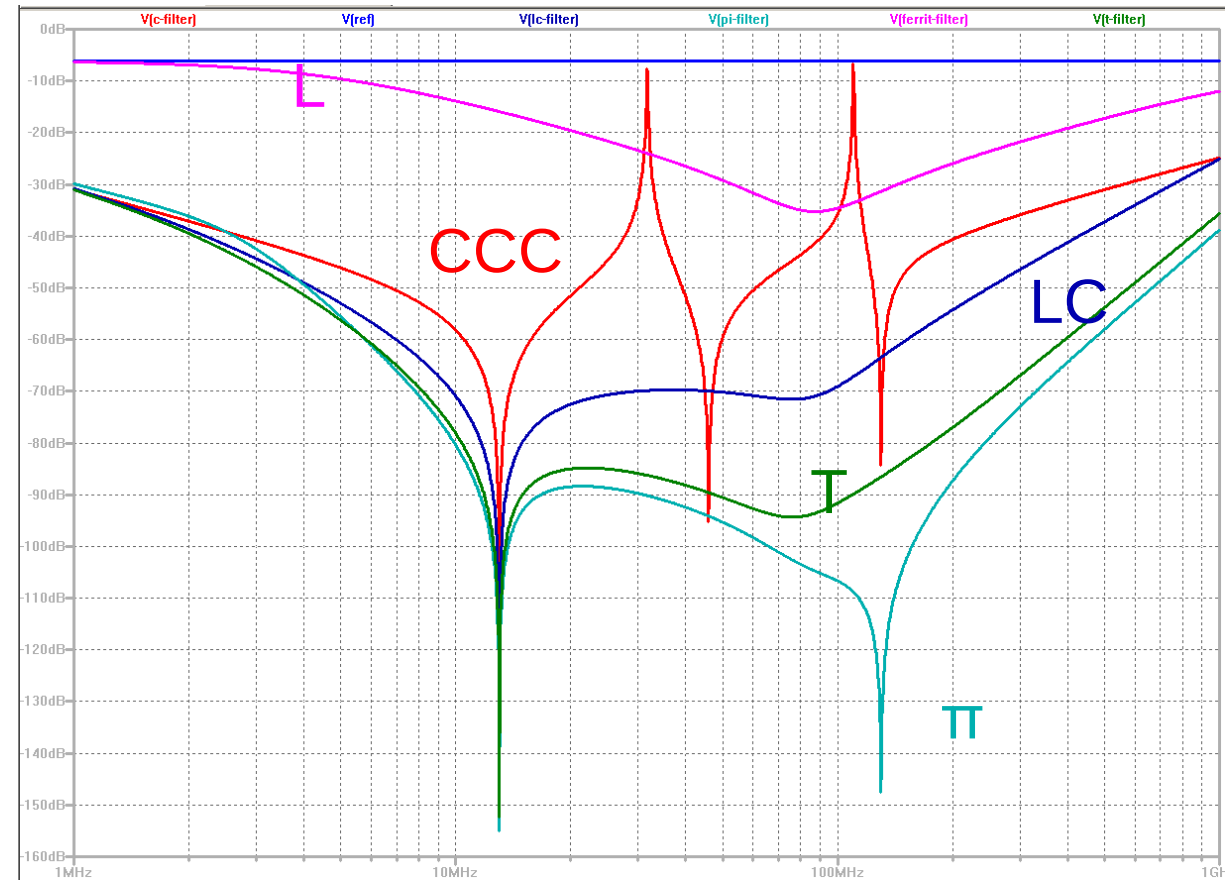
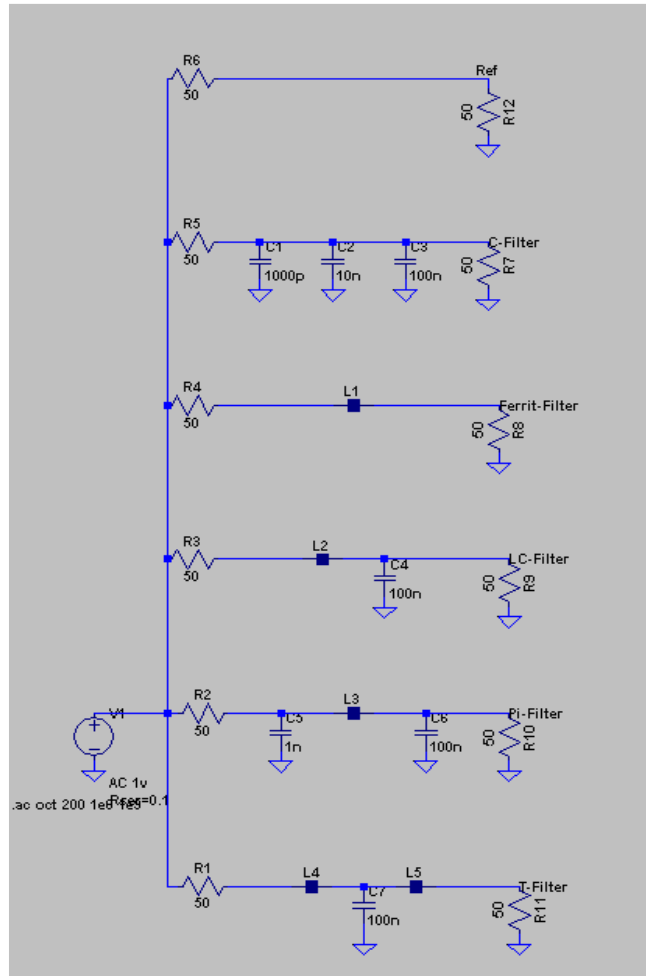
WE eiSos



$$|A|_{dB} = 20 * \log_{10} \left(\frac{Z_A + Z_F + Z_B}{Z_A + Z_B} \right)$$

Eigenresonanz
der Bauteile
beachten!

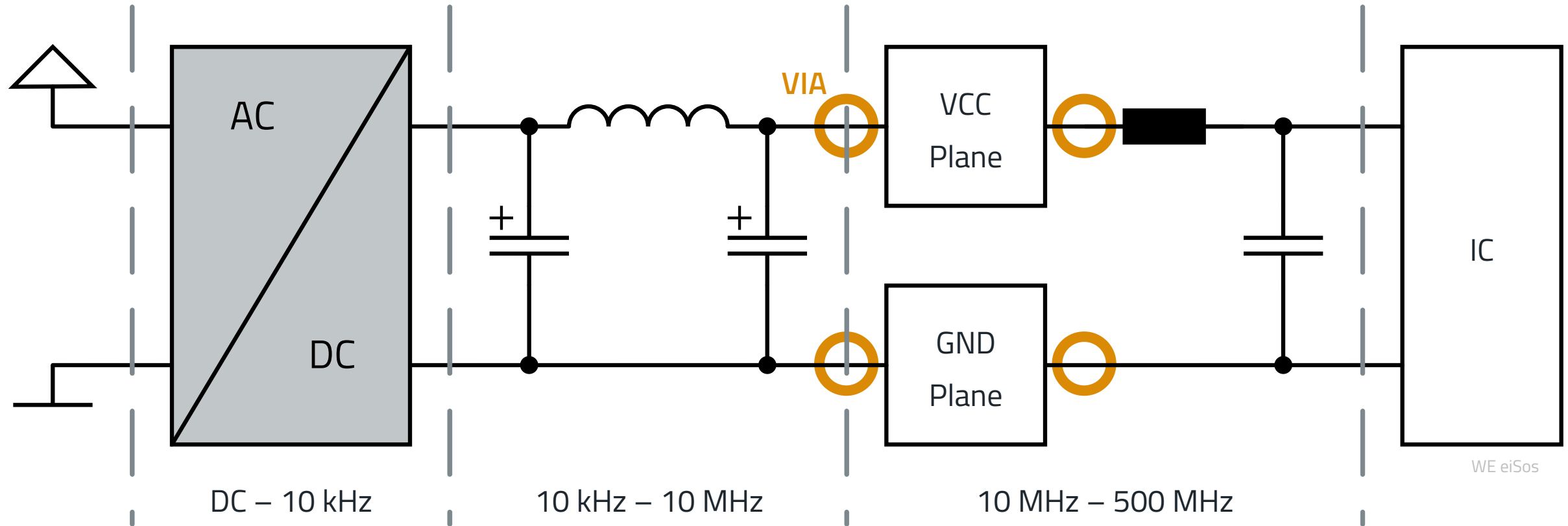
Filtertopologien - Dämpfung



WOHIN MIT DEM FILTER?

Filter Placement

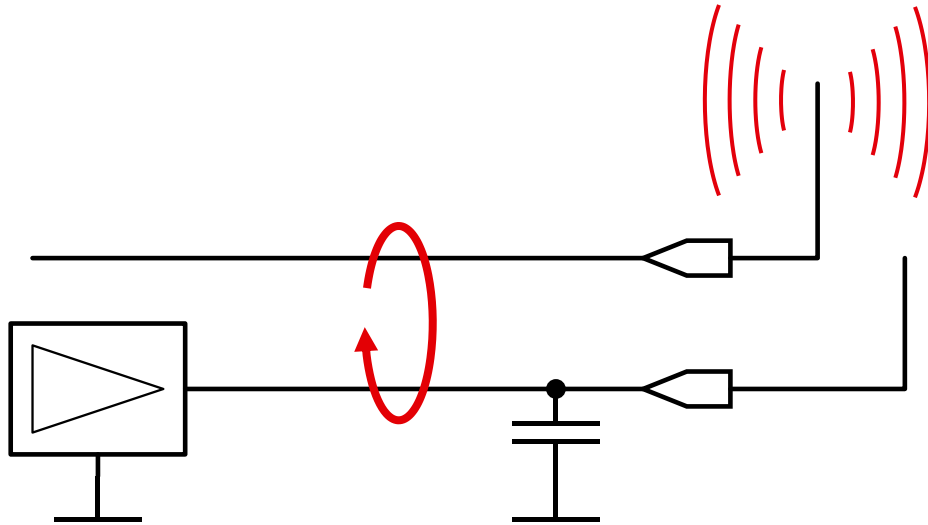
Filter Bandwidth Requirements along the Power Path



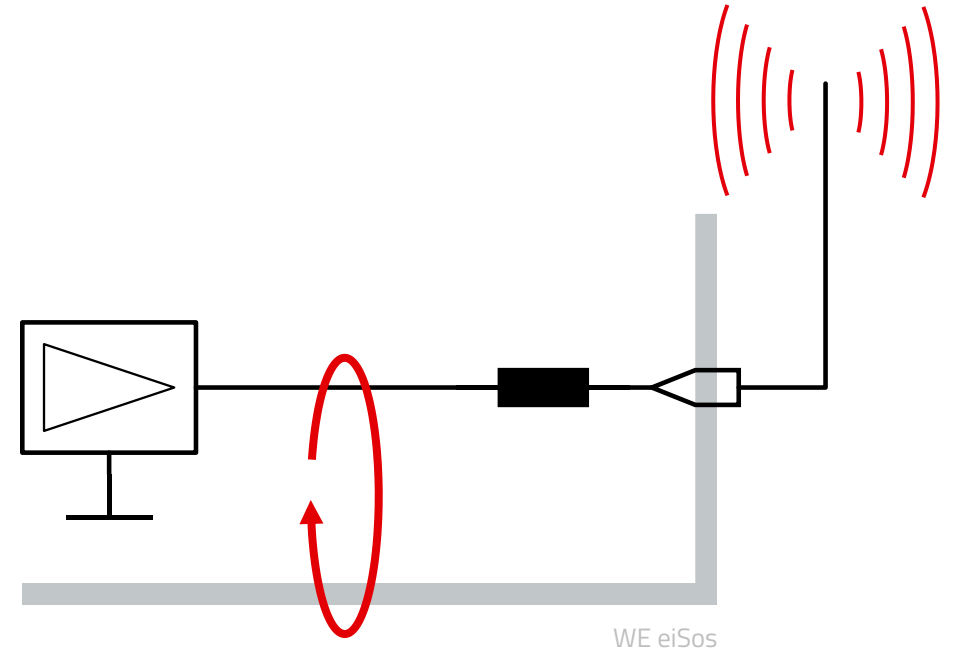
WE eiSos

Filter Placement

Noise can bypass a misplaced Filter



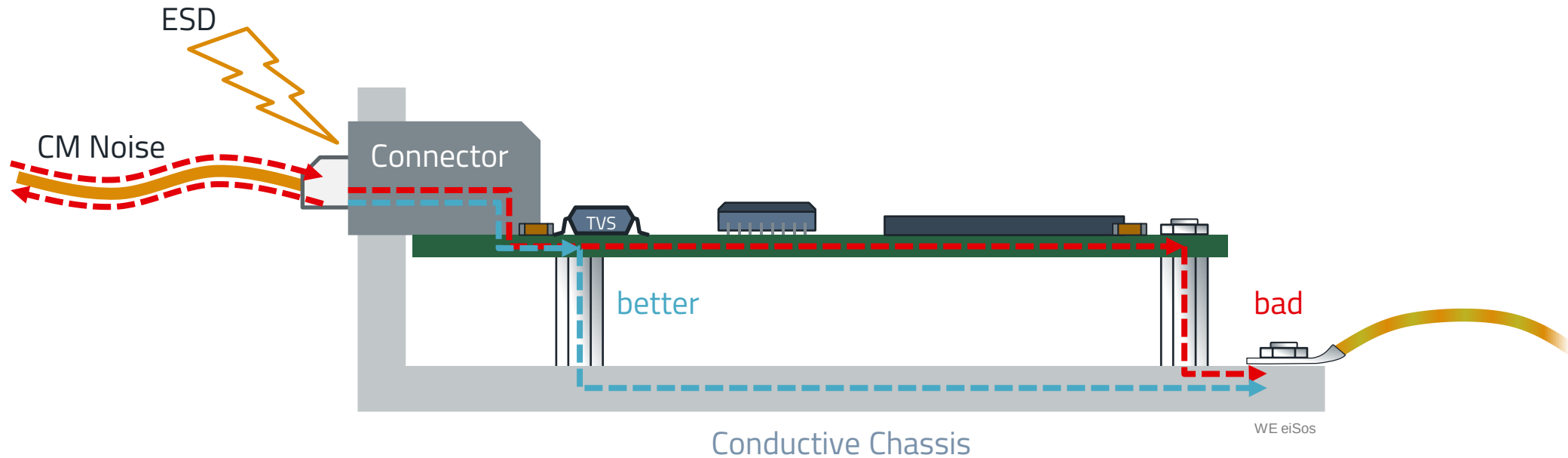
Bypassing via parallel Lines



Bypassing via chassis parts

Filter Placement

Diverting Noise to Earth



- Grounding studs have to be placed so that disturbances don't affect the electronic parts
- Reference ground for ESD (and common mode noise) is earth potential

